

Exceptional service in the national interest



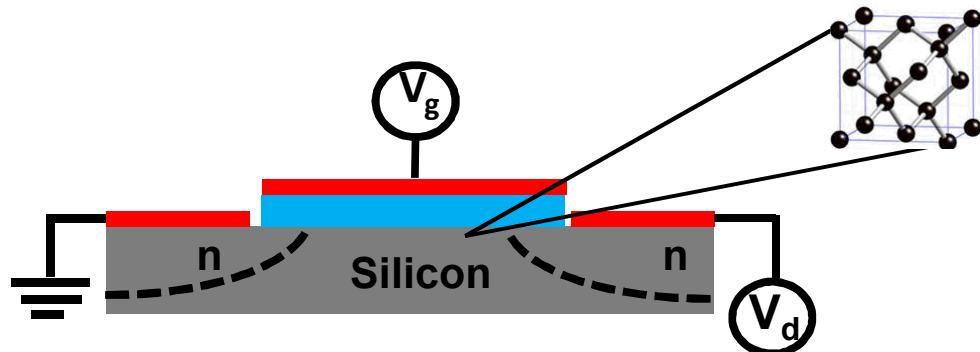
Molecule meets MOF: bridging the gap between organic and inorganic electronic materials

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SPIE Optics and Photonics 2014 Meeting
August 20, 2014

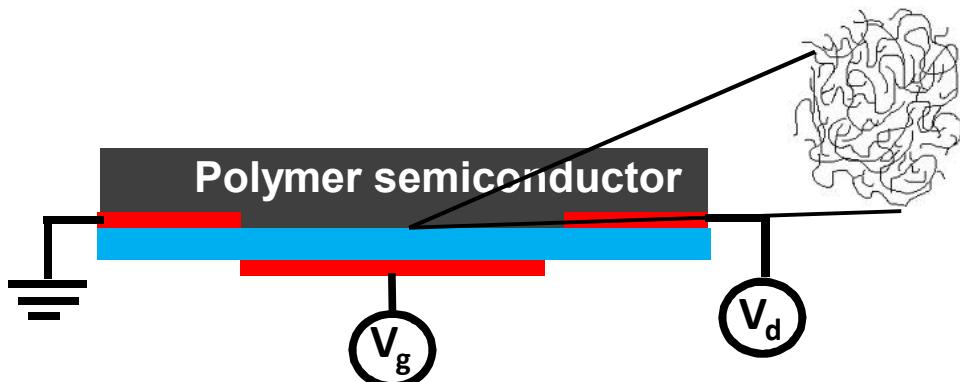
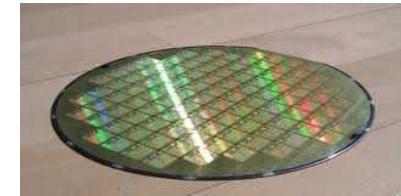
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Inorganic vs. organic conducting materials: the best and the worst of two worlds



Crystalline inorganic semiconductors

- High mobility
- Stability
- **High cost**
- Non-flexible
- Limited tailorability
- Radiation damage

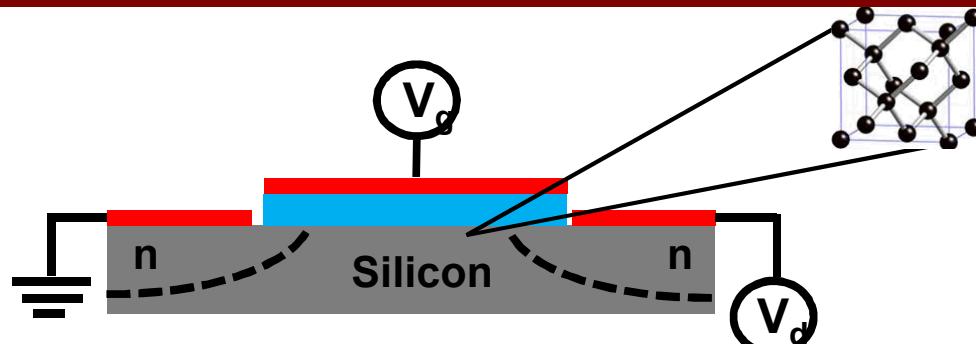


Disordered organic semiconductors

- Flexible
- Tunable w/ chemistry
- Low cost fabrication
- **Poor mobility**
- Instability
- Low free carrier densities

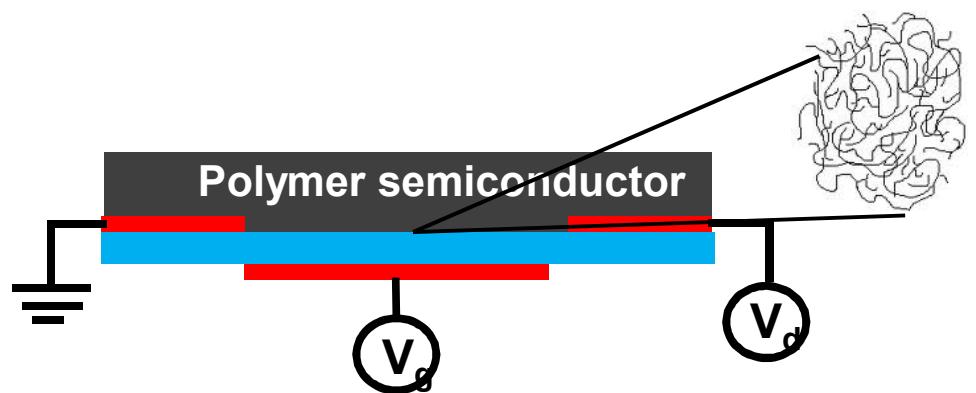
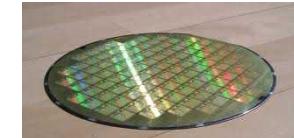


Can the high performance of inorganic semiconductors with the tailorability of organic materials be achieved using MOFs?



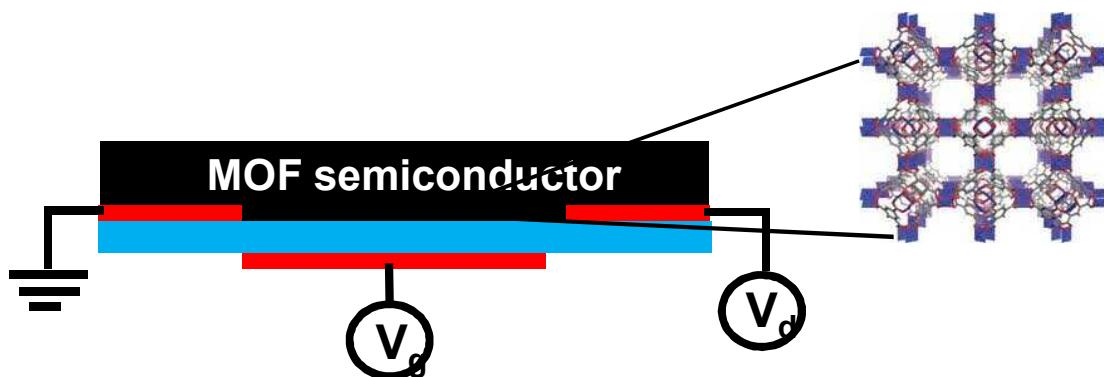
Crystalline inorganic semiconductor

- High mobility
- Stability
- High cost
- Non-flexible
- Radiation damage



Disordered organic semiconductor

- Flexible
- Tunable w/ chemistry
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- Low free carrier densities



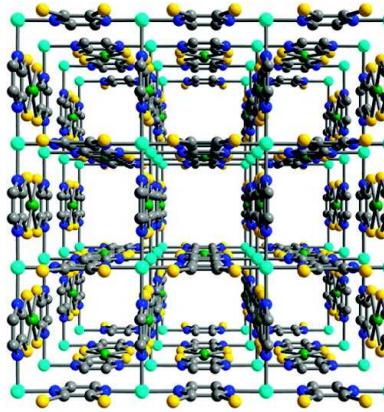
Crystalline MOF semiconductor

- Structurally flexible
- Tunable w/ chemistry
- Scalable to nanometers
- Low cost fabrication
- Reconfigurable electronics
- Rad-hard
- Novel electronic material

MOFs combine features of inorganic and organic materials

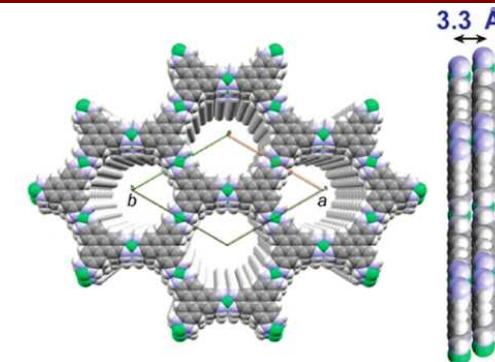
Electrically conducting porous MOFs are rare

- **p-type Cu-Ni Dithiolene MOF**
- **MET-3 (Fe-triazolate MOF)**
- **Mn(thiophenol) MOF: $(-\text{Mn}-\text{S}-)^\infty$ chains**
- **Metal-Organic Graphene analogues (MOGs)**

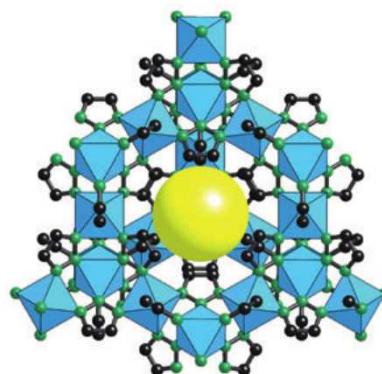


Y. Kobayashi et al.

Chem. Mater. 2010, 22, 4120



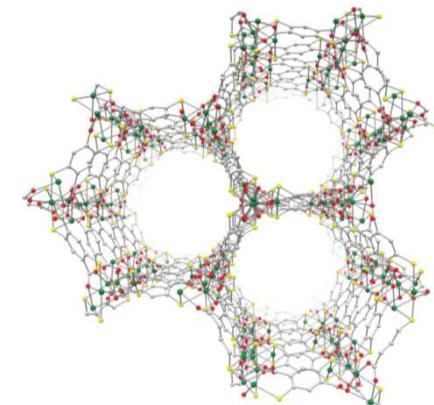
$\text{Ni}_3(\text{HITP})_2$ MOG
D. Sheberla et al.
JACS 2014 ASAP



MET-3 (Fe)

Gándara et al.

Chem. Eur. J. 2012,
18, 10595



Mn(thiophenol) MOF

L. Sun et al.

J. Am. Chem. Soc.
2013, 135, 8185

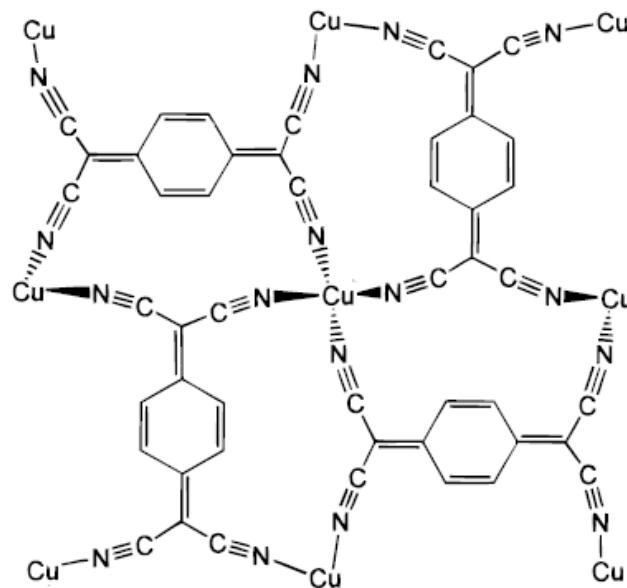
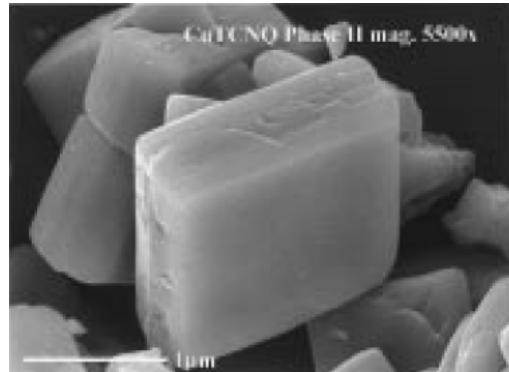
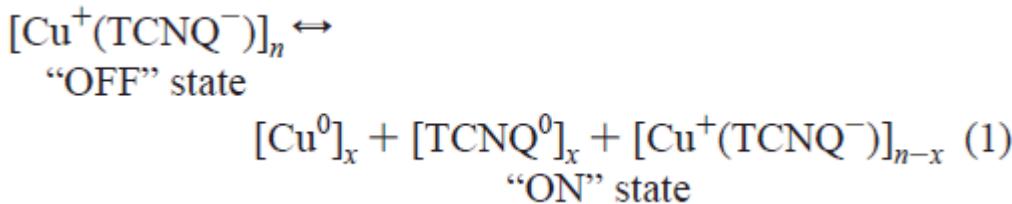
Cu-TCNQ is a well-known conducting coordination polymer

144

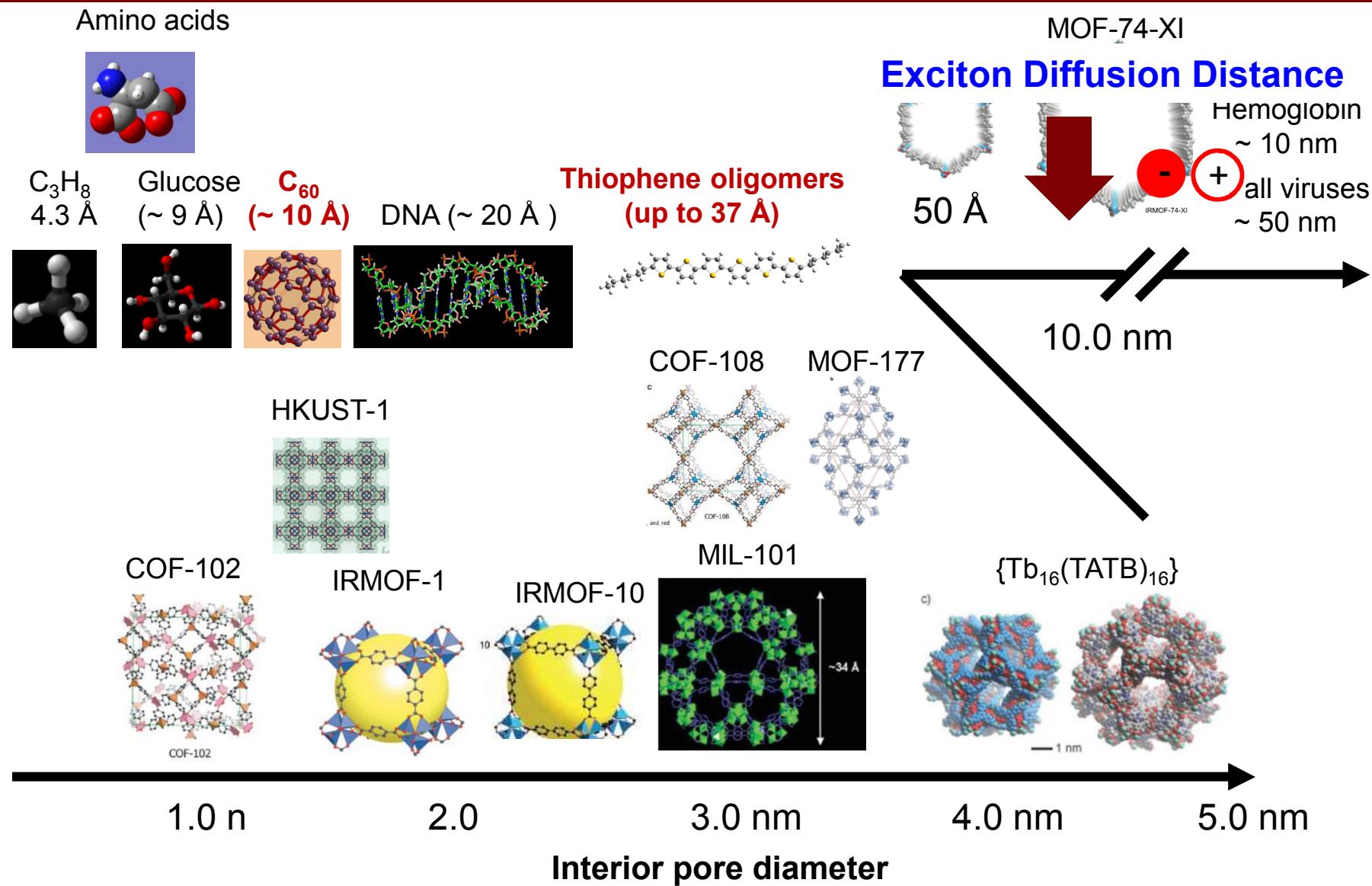
Inorg. Chem. 1999, 38, 144–156

New Insight into the Nature of Cu(TCNQ): Solution Routes to Two Distinct Polymorphs and Their Relationship to Crystalline Films That Display Bistable Switching Behavior

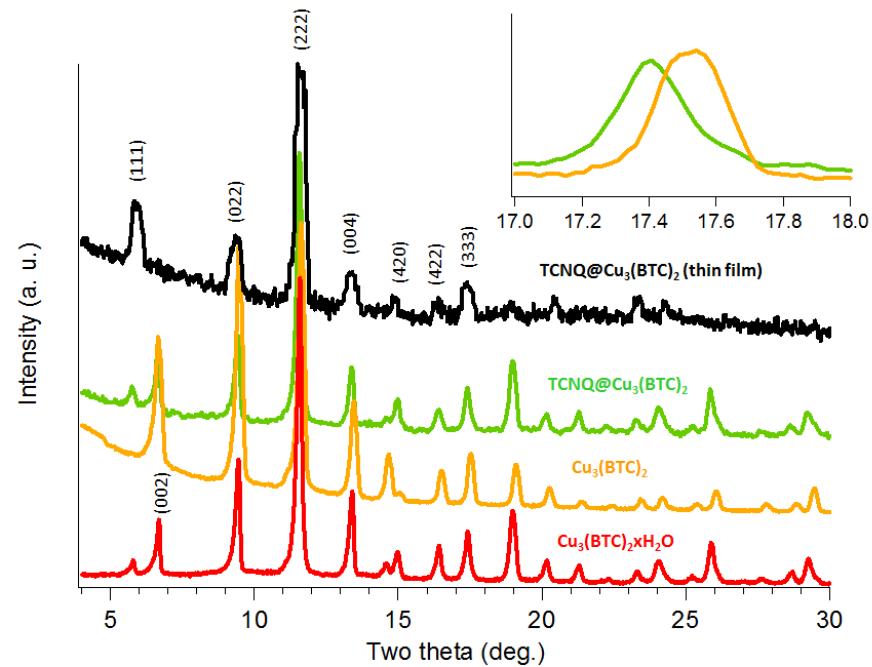
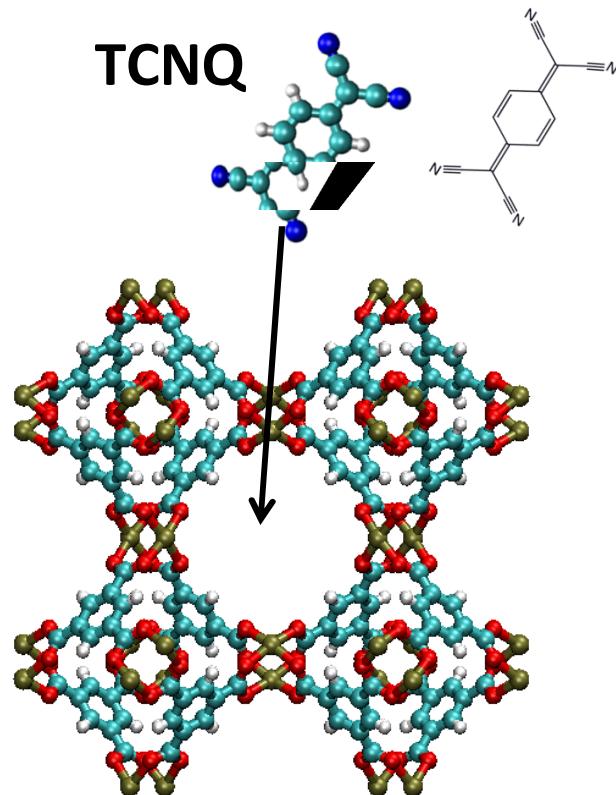
Robert A. Heintz,[†] Hanhua Zhao,[†] Xiang Ouyang,[†] Giulio Grandinetti,[†] Jerry Cowen,[‡] and Kim R. Dunbar,^{*,†}



Guest molecule + MOF \rightarrow ordered, tunable platform for controlling interactions at the nanoscale

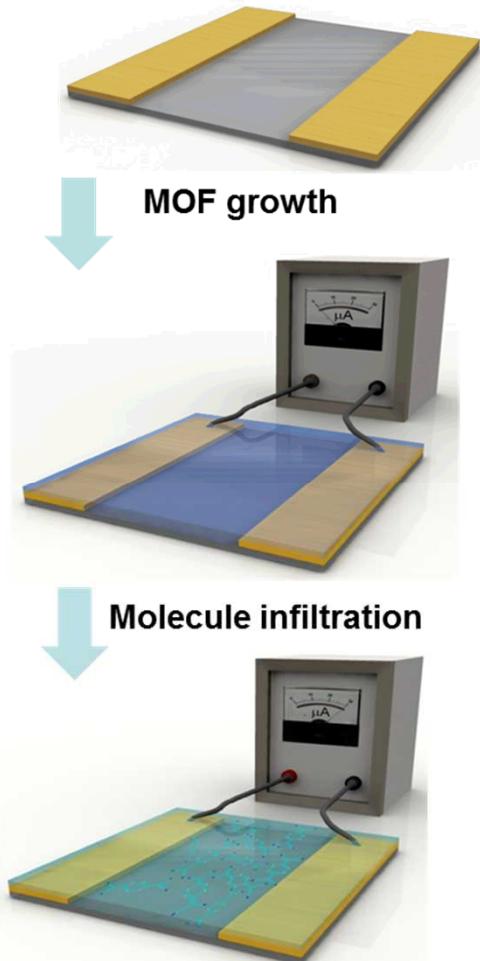


Guest@MOF: Emergent properties by infiltrating with guest molecules?

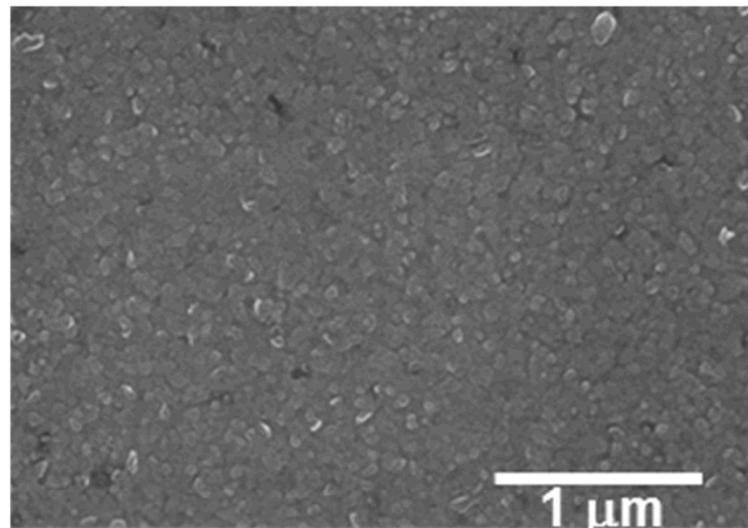


TCNQ loading: ~ 1 molecule/large pore

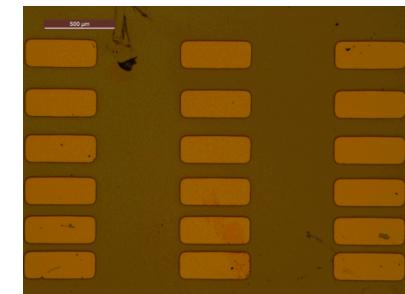
TCNQ \rightarrow Cu₂(BTC)₃ leads to color change...



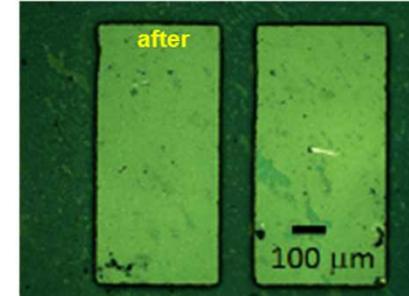
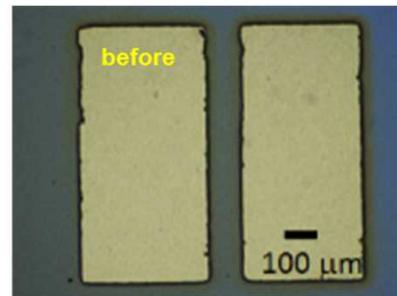
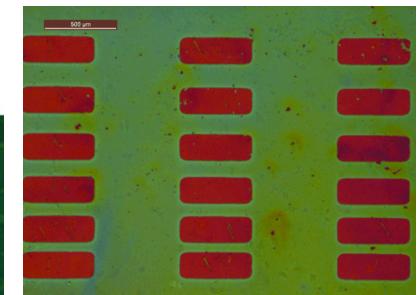
MOF film grown by layer-by-layer method



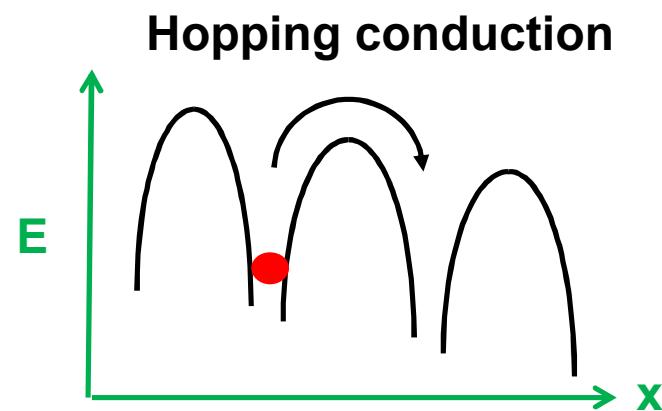
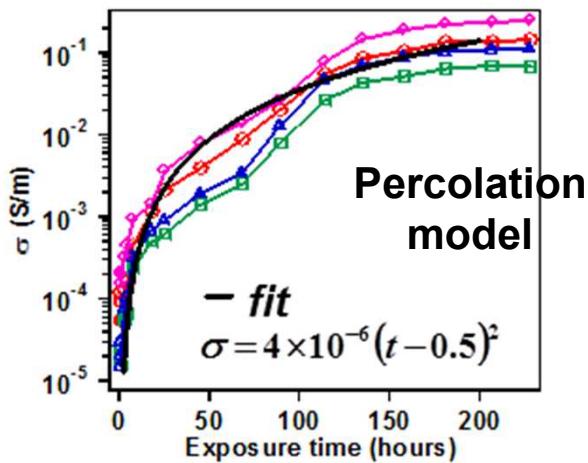
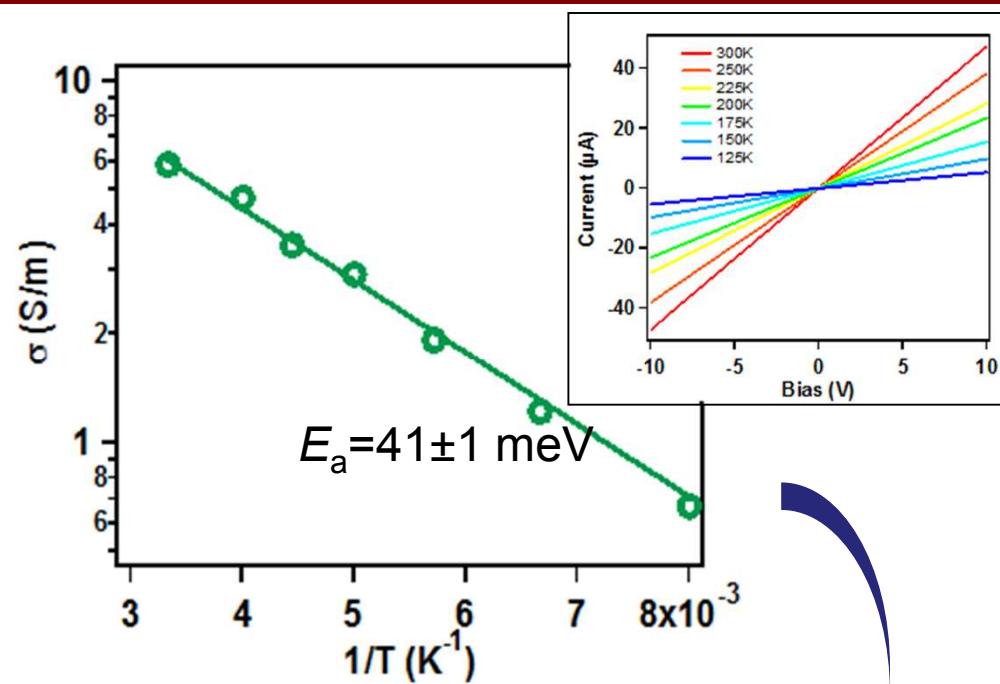
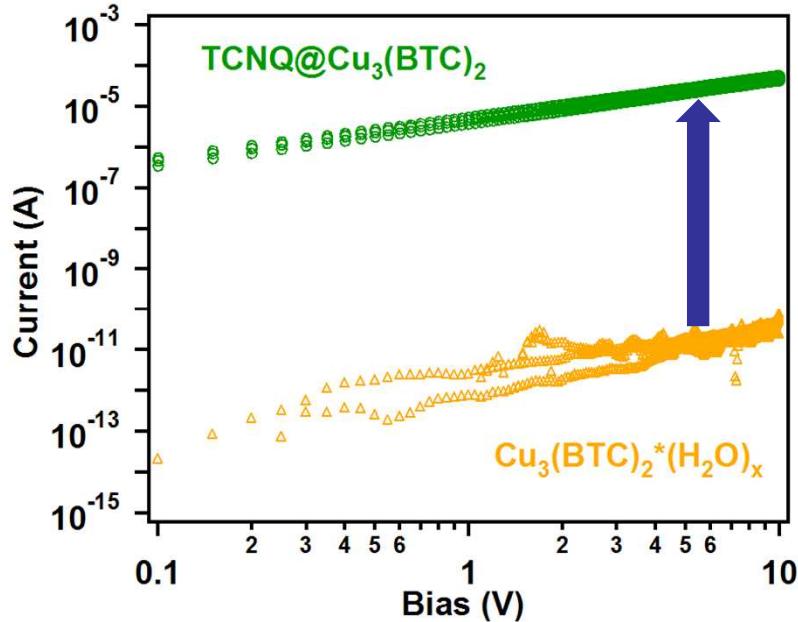
MOF film on SiO_x with Pt electrodes



MOF film + TCNQ

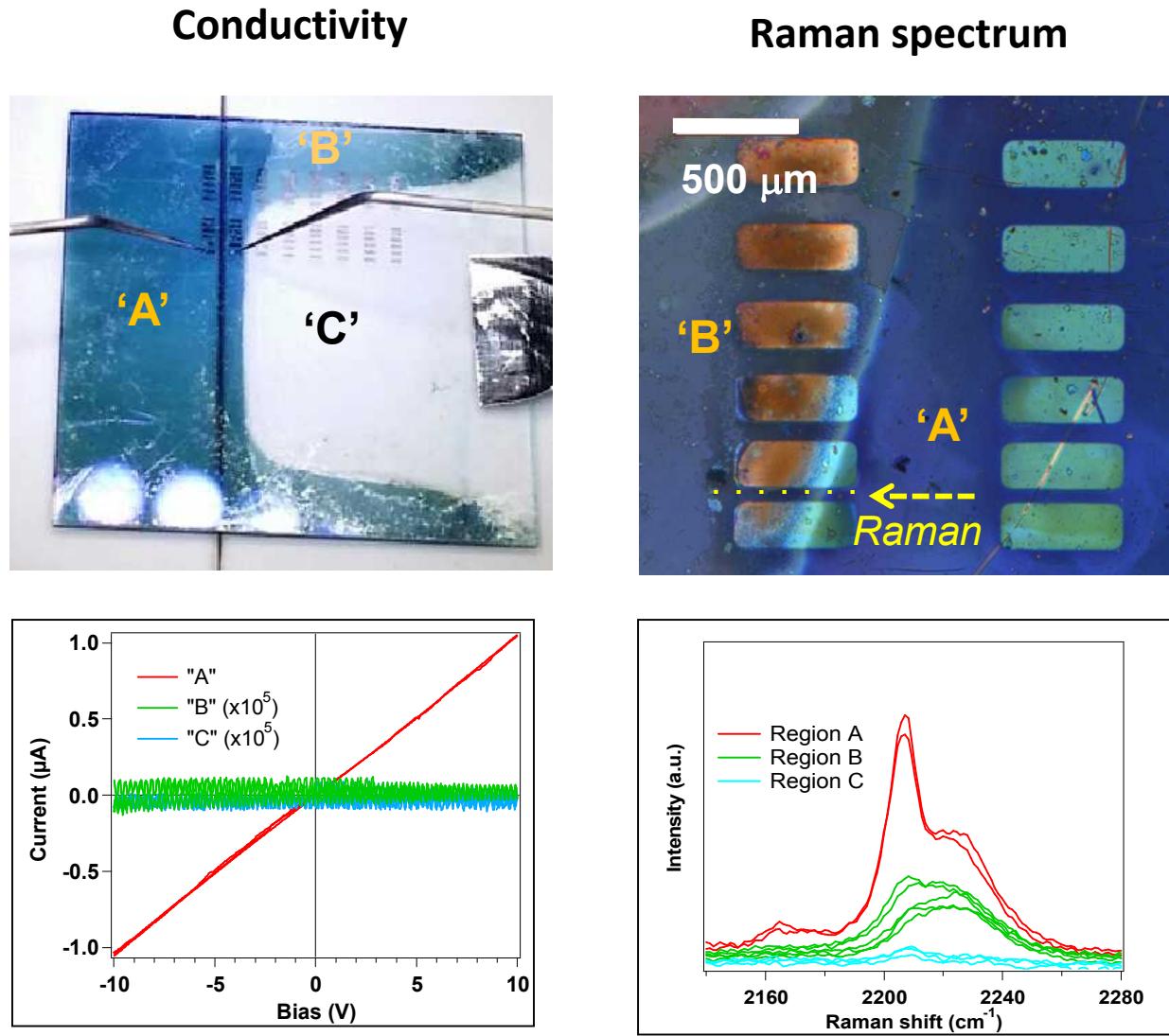


... and $>10^7$ increase in conductivity, air stable > 1 year

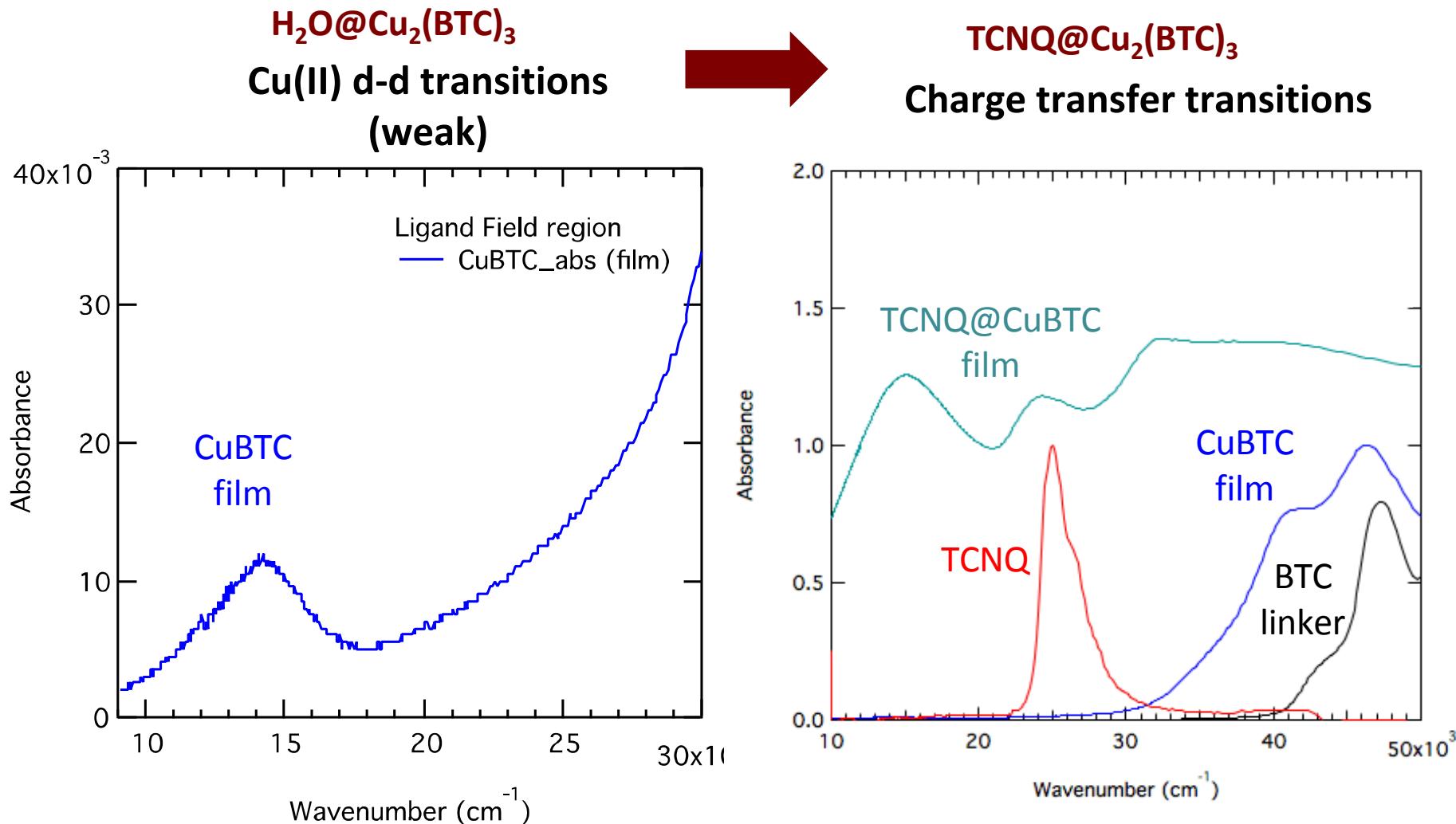


C≡N stretch splitting in Raman spectrum observed only inside dark colored, conducting region

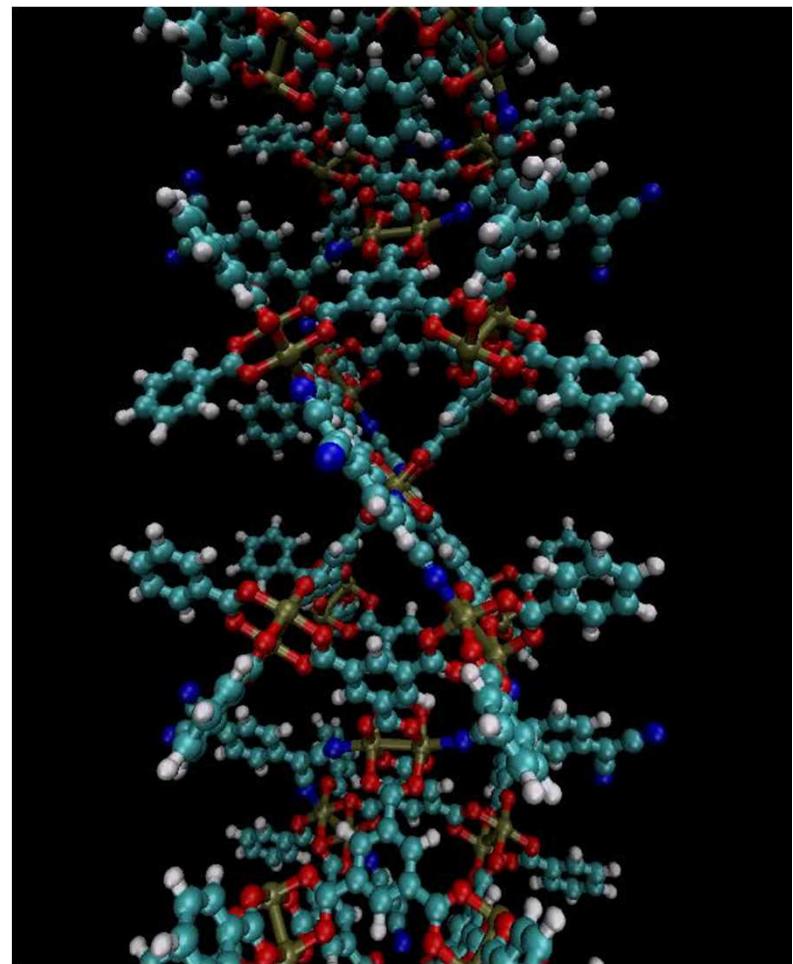
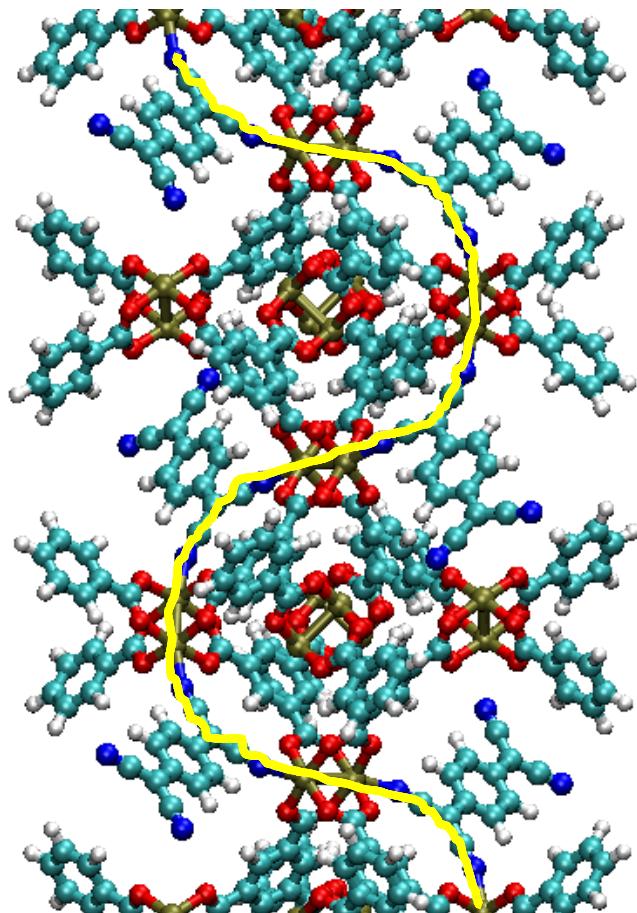
Patterned substrate
immersed in TCNQ
solution



TCNQ@Cu₂(BTC)₃ exhibits strong new absorption bands



DFT: Cu(II) dimers linked by TCNQ

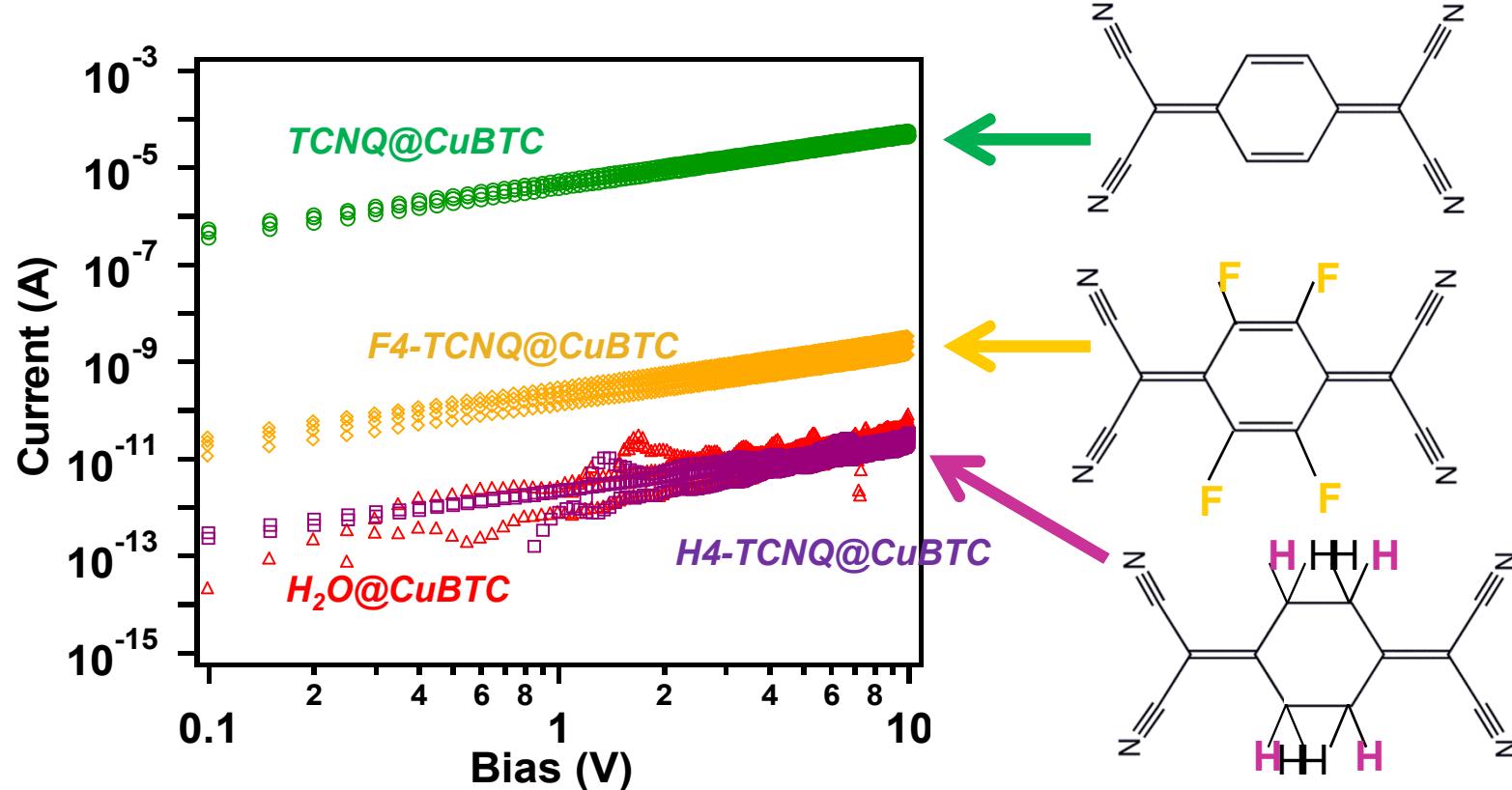


Continuous TCNQ@CuBTC pathway is achievable with 4 TCNQs

Experimental loading = 8 TCNQs/unit cell → two continuous pathways are possible

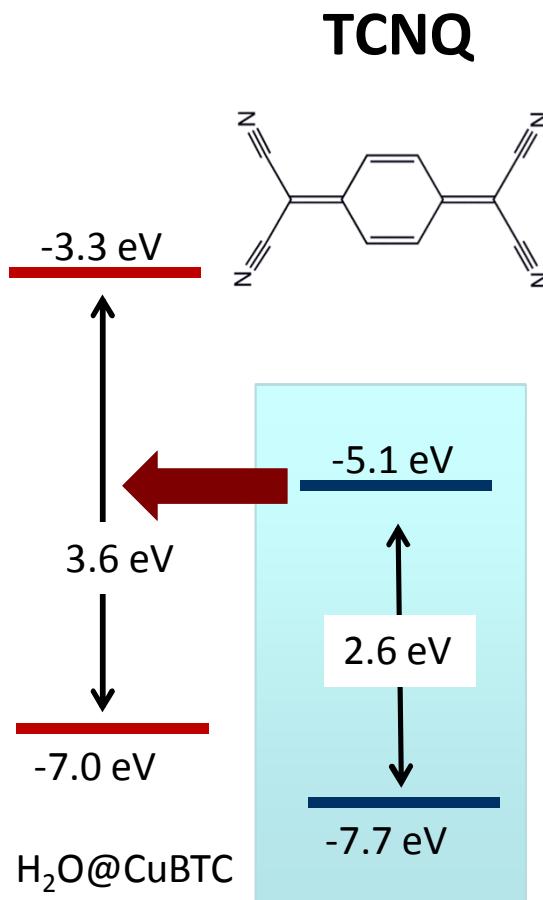
Guest aromaticity, electronegativity affect conductivity

Extended π network essential for conductivity

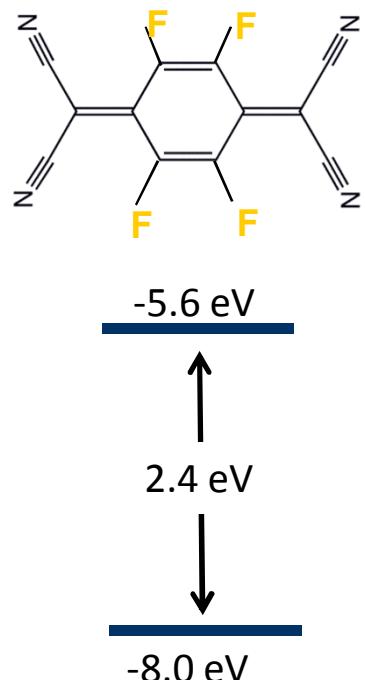


Cu-BTC band alignments: DFT/PBEsol calculations

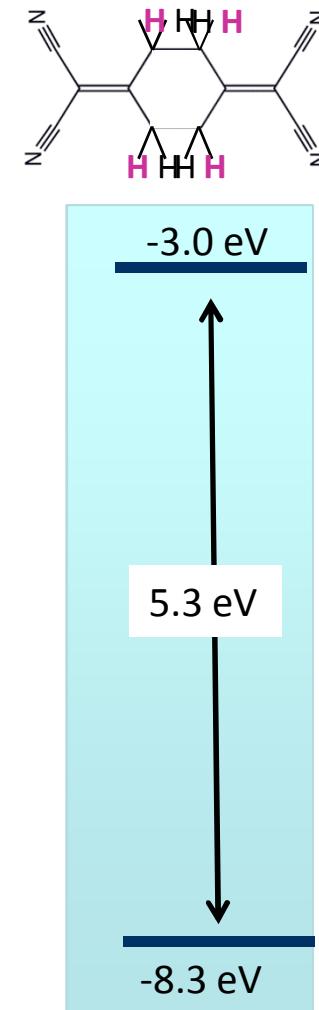
Effect of fluorination and hydrogenation of TCNQ



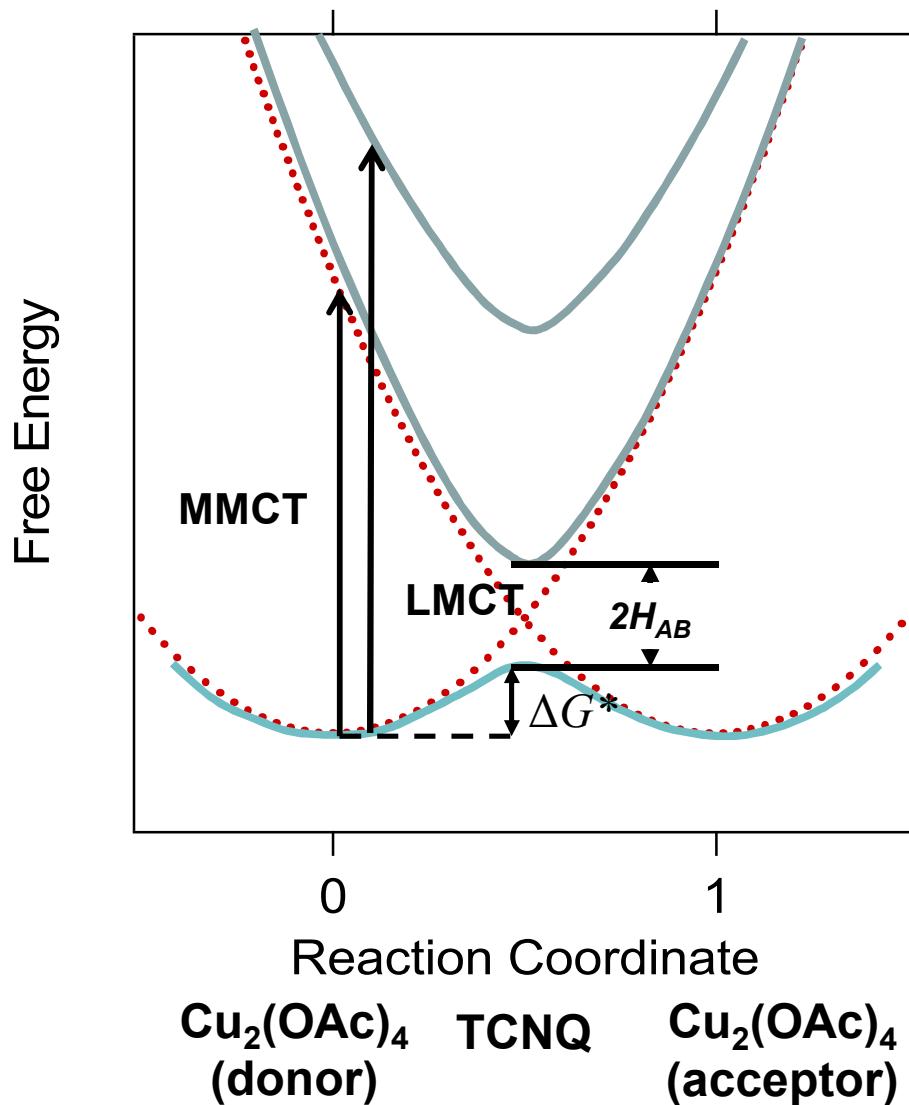
$\text{F}_4\text{-TCNQ}$



$\text{H}_4\text{-TCNQ}$



TBCNQ increases coupling between neighboring Cu dimers → lowers barrier to charge transfer



Three-site model: Donor-Bridge Acceptor

H_{AB} -Electronic coupling matrix element

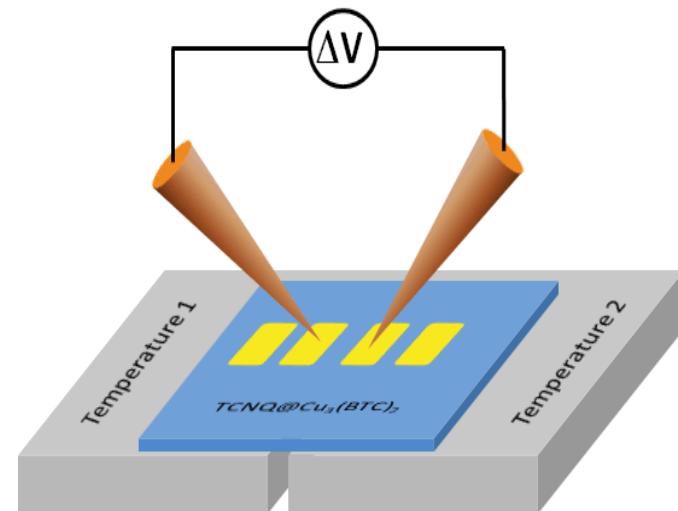
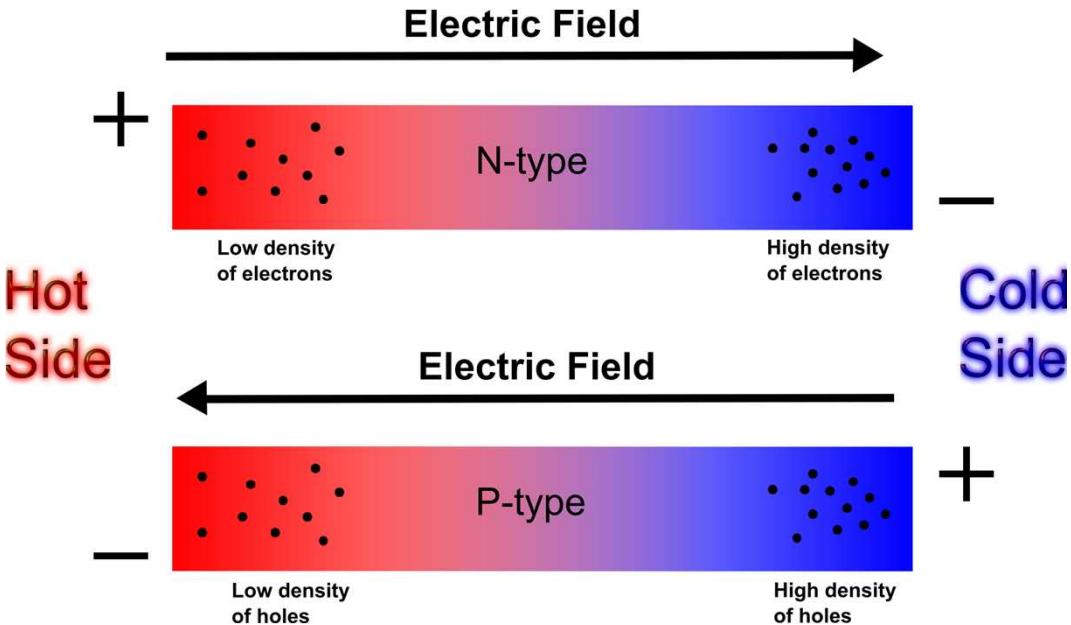
$$H_{AB} = \langle \Psi_A | H | \Psi_B \rangle$$

Computed by Constrained DFT:

$\text{H}_4\text{-TCNQ} < \text{F}_4\text{-TCNQ} < \text{TCNQ}$

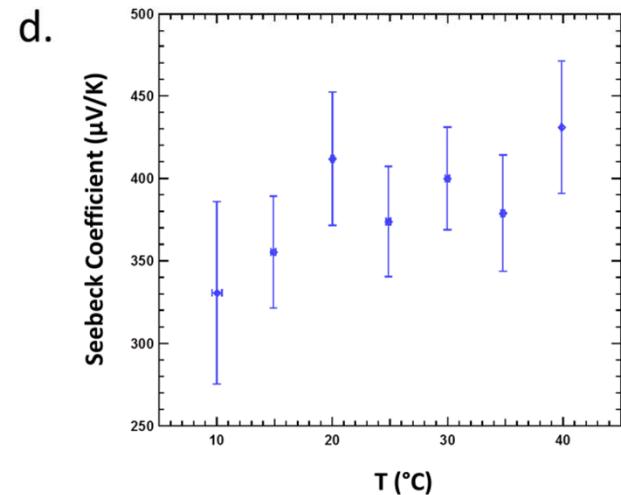
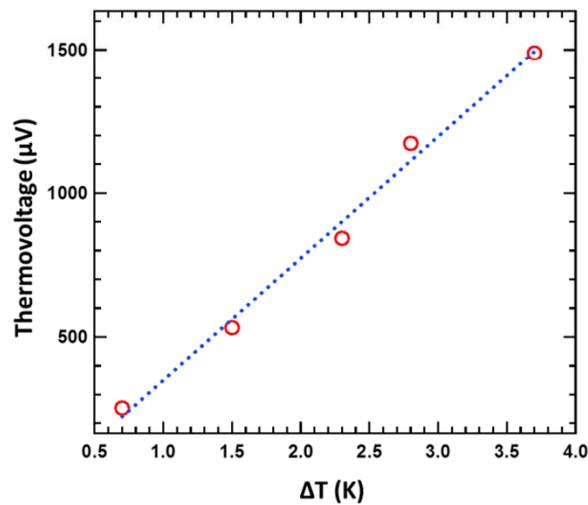
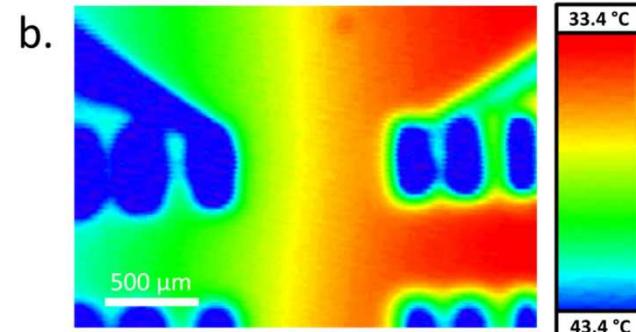
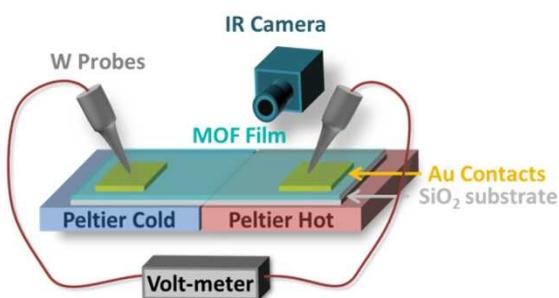
$H_{AB} = 0.19 \text{ eV} < 1.03 \text{ eV} < 2.32 \text{ eV}$

What about the carrier type (electron or hole?) Seebeck effect is one way to find out...

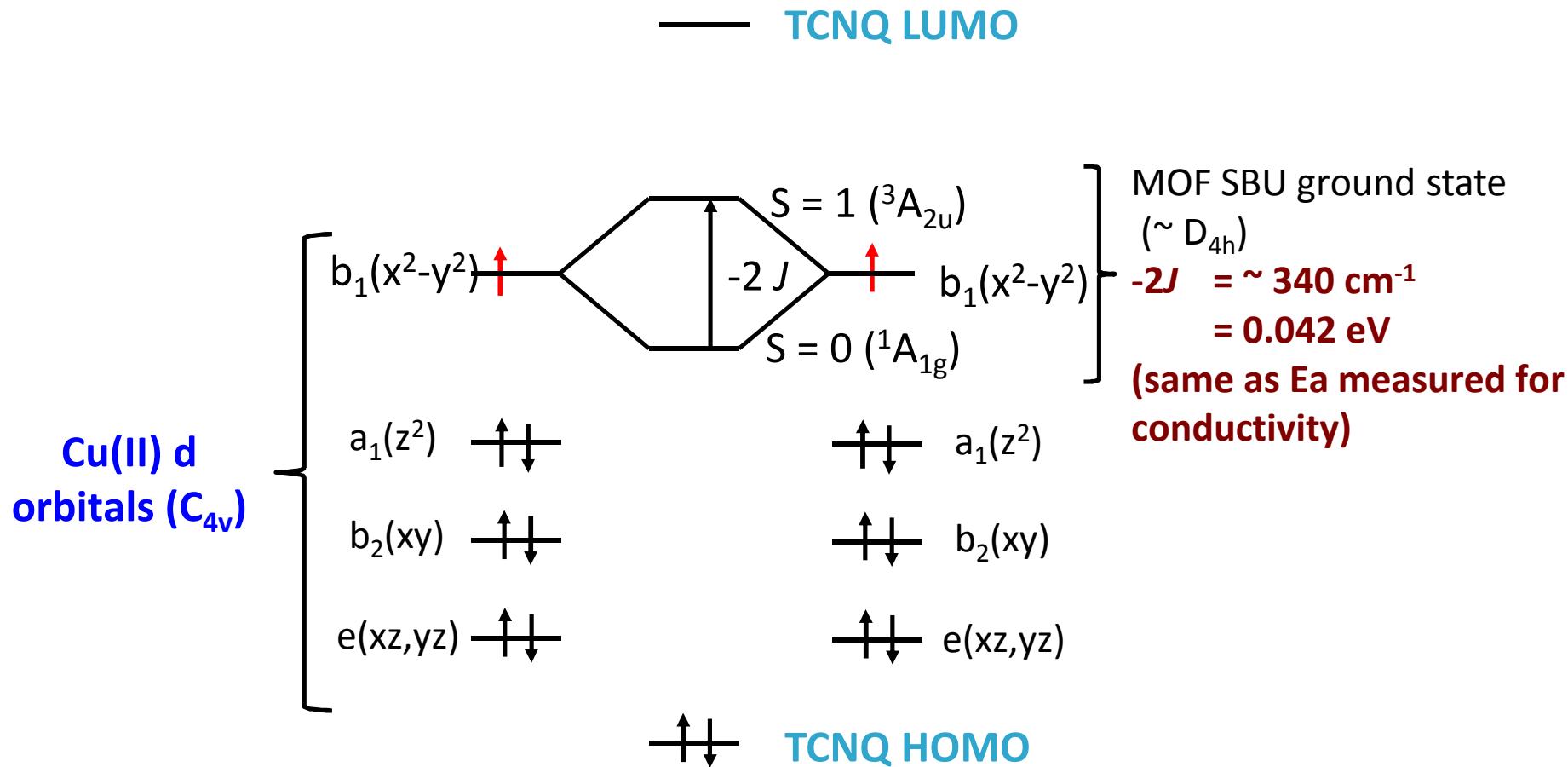


Thermoelectric measurements of TCNQ@Cu₃(BTC)₂

- Majority carrier: holes
 - High Seebeck coefficient
 - ~400 $\mu\text{V/K}$ vs.
 - 170 $\mu\text{V/K}$ for Bi₂Te₃
- promising material for thermoelectrics



Electronic structure of TCNQ@Cu₃(btc)₂



Conclusions

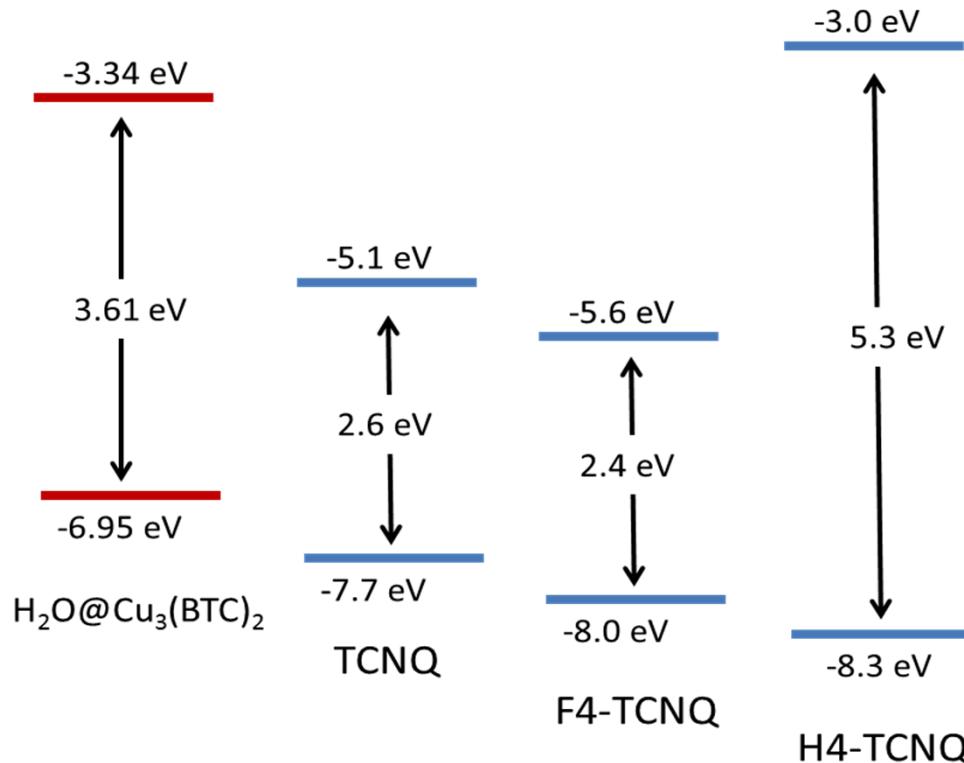
- MOFs are hybrid materials with ordered, chemically tunable porosity
- MOF thin films can be grown layer-by-layer from solution
- Conductivity of $\text{Cu}_3(\text{BTC})_2$ tunable $10^{-8} \rightarrow 10^{-1}$ S/cm with TCNQ
- UV-Vis, IR indicate partial charge transfer
- Opportunities for tuning properties w/ molecule@MOF expanding

Acknowledgements

- Kris Erickson
- Alexandra Ford
- Michael Foster
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- Francois Léonard
- Kirsty Leong
- Catalin Spataru
- Vitalie Stavila
- Alec Talin
- NIST: Andrea Centrone, Paul Haney, R. Adam Kinney, Veronika Szalai, Heayoung P. Yoon

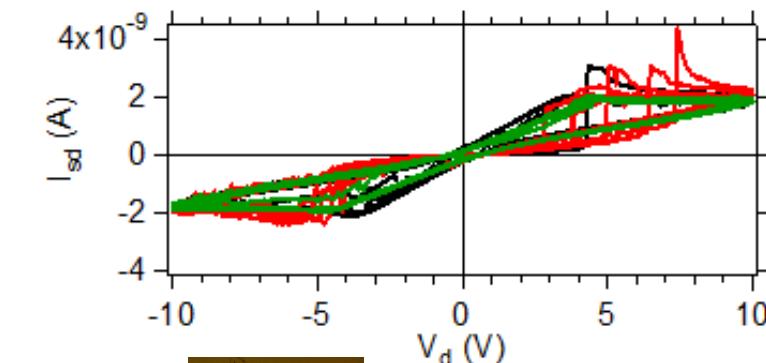


Backup Slides

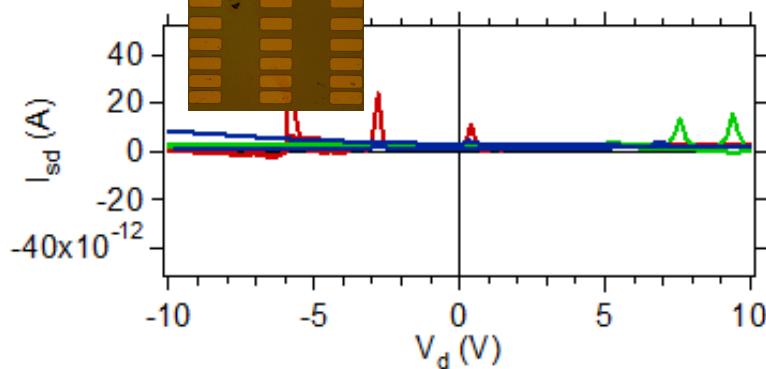


A schematic representation of the alignment of the HOMO/LUMO orbitals and bandgaps of $\text{H}_2\text{O}@\text{CuBTC}$, TCNQ, F4-TCNQ, and H4-TCNQ determined at the UB3LYP/VTZP level of theory.

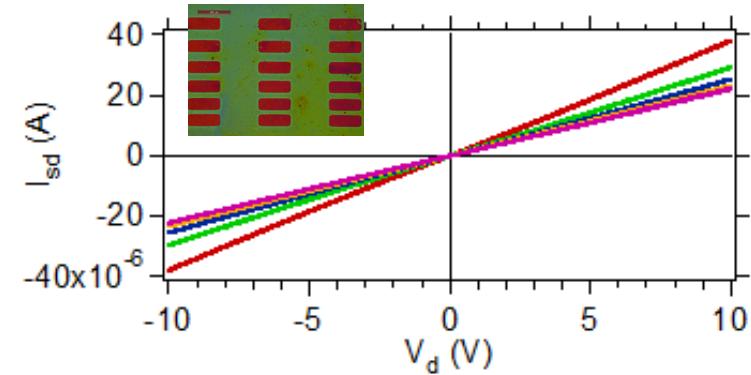
Solvent, precursor likely responsible for conductivity in as deposited $\text{Cu}_3(\text{BTC})_2$



As deposited: Low but measurable conductivity, ionic/electronic?



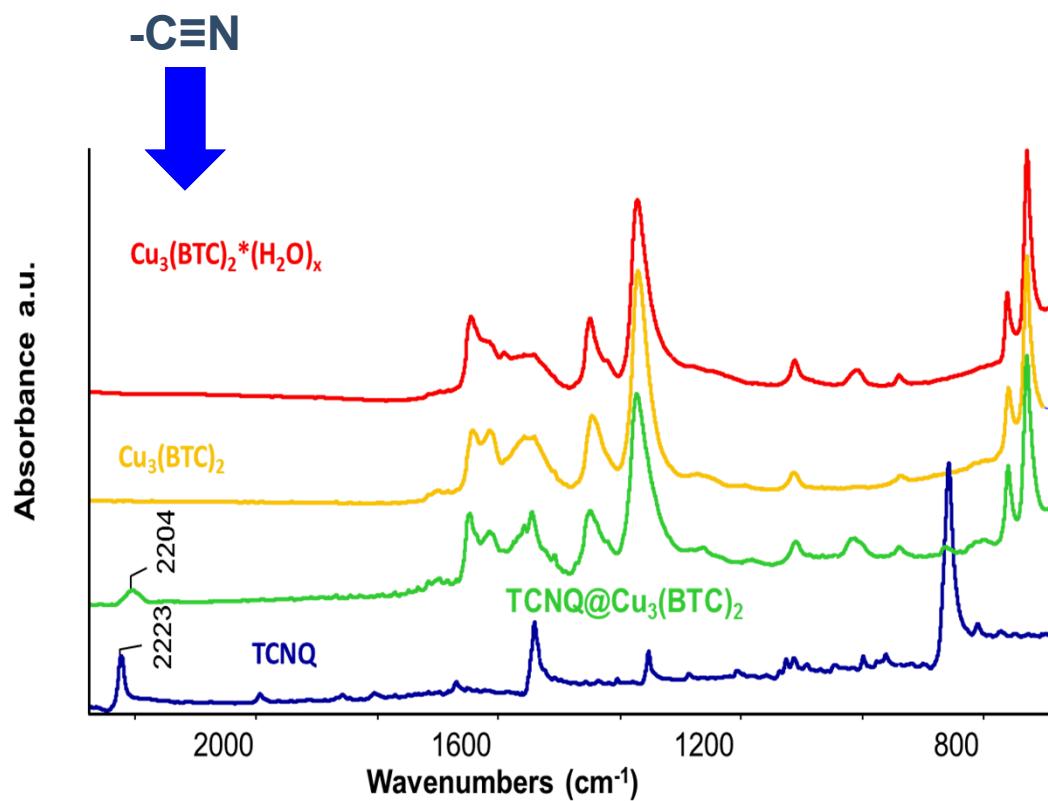
Activated, exposed to ambient: No measurable conductivity at 10 V ($<10^{-12}$ A)



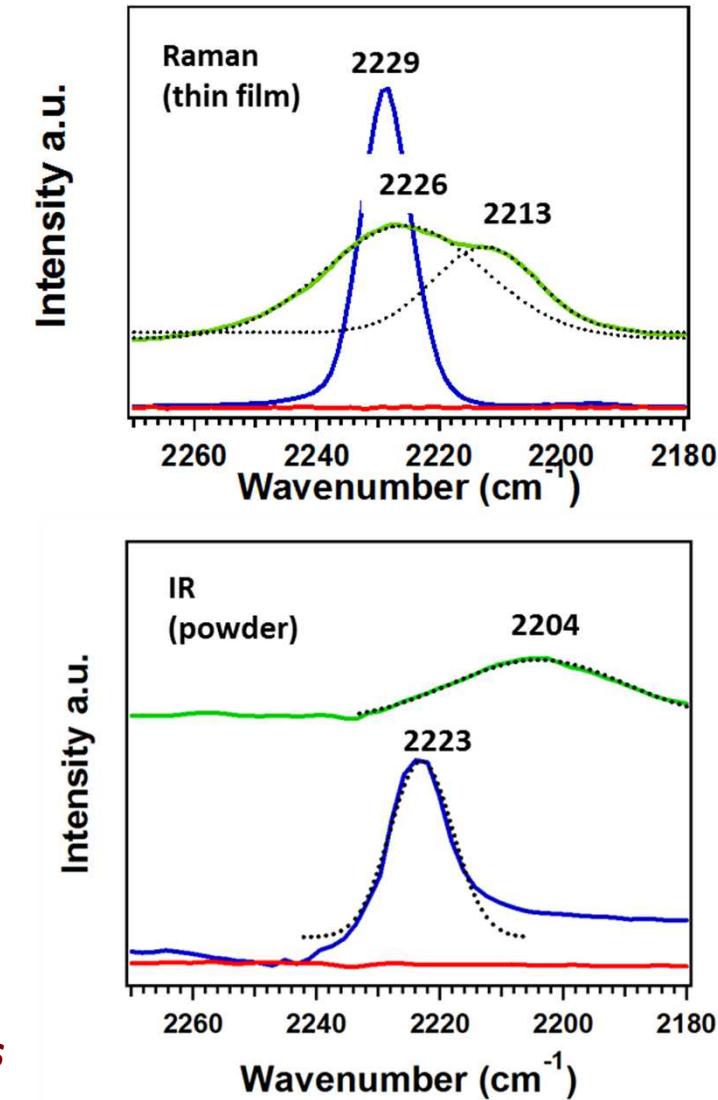
Infiltrated MOF (trace water): $s \sim 0.1$ S/cm, $\sim 10^8$ increase

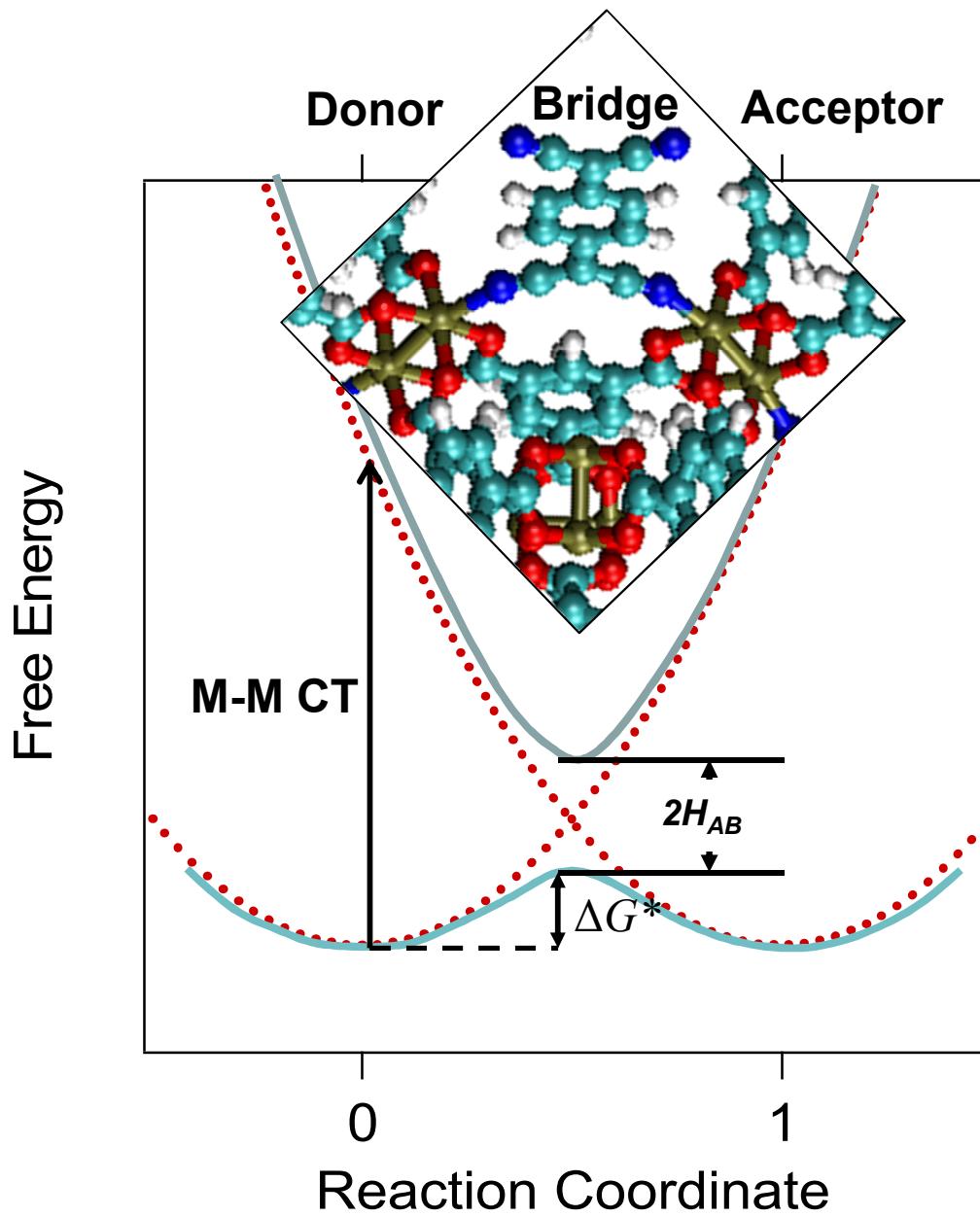
Vibrational spectra show shift of $-\text{C}\equiv\text{N}$ indicates charge transfer

$$z = (v_o - v) / 44 \text{ cm}^{-1} \approx 0.43e$$



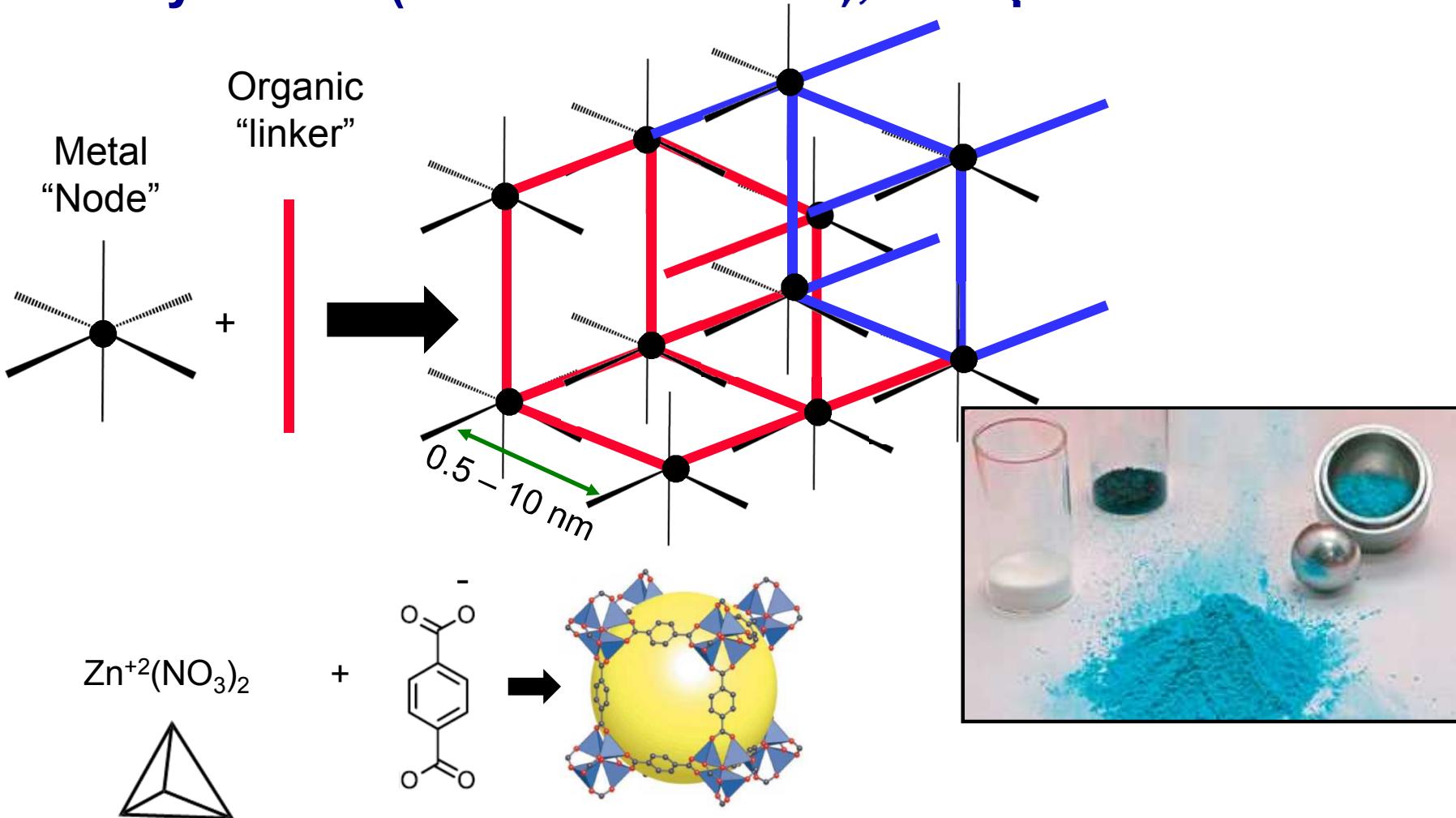
Raman peak splitting indicates 2 inequivalent CN groups



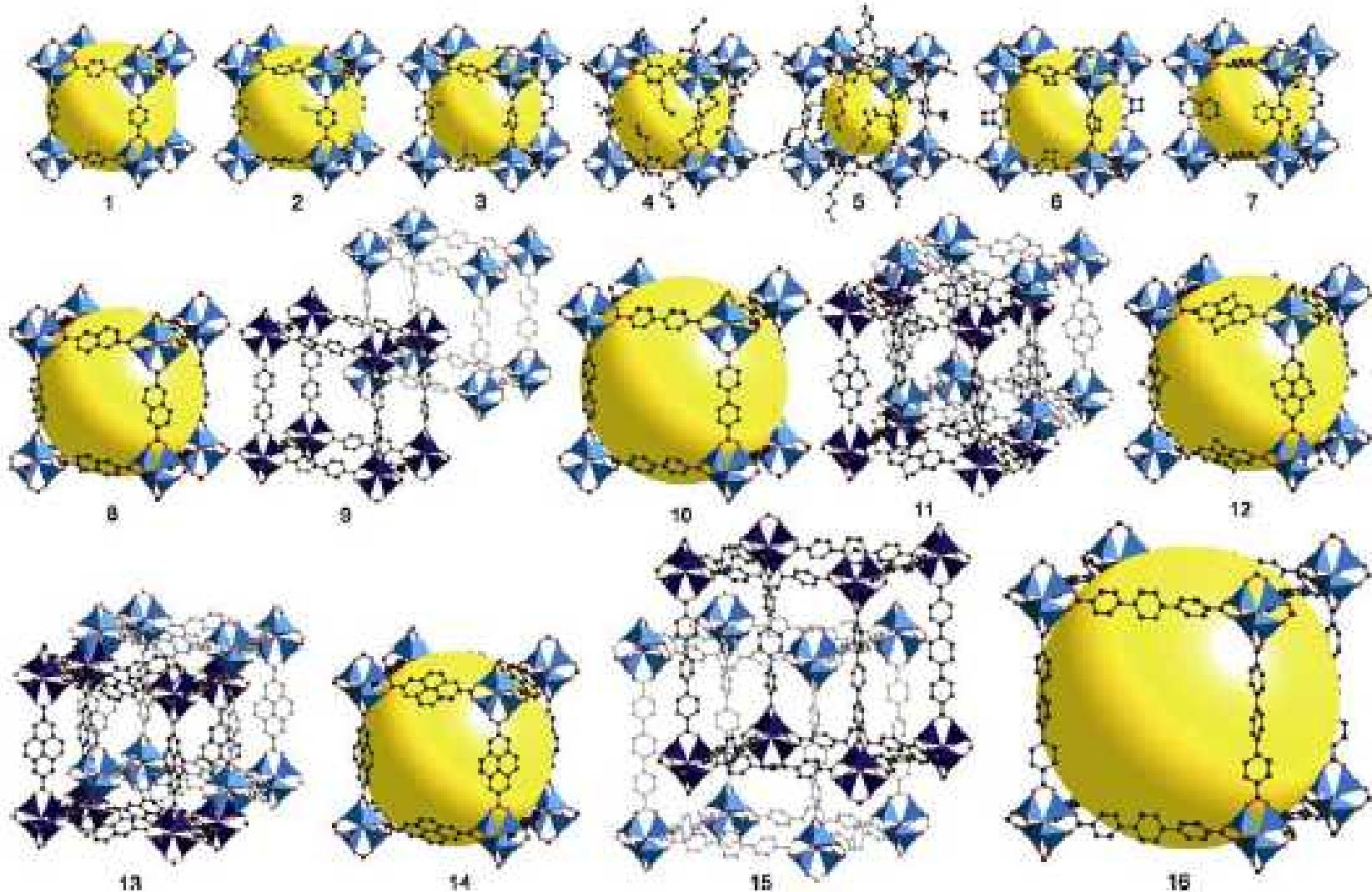


What is a Metal-Organic Framework?

Crystalline (therefore ordered), nanoporous structure

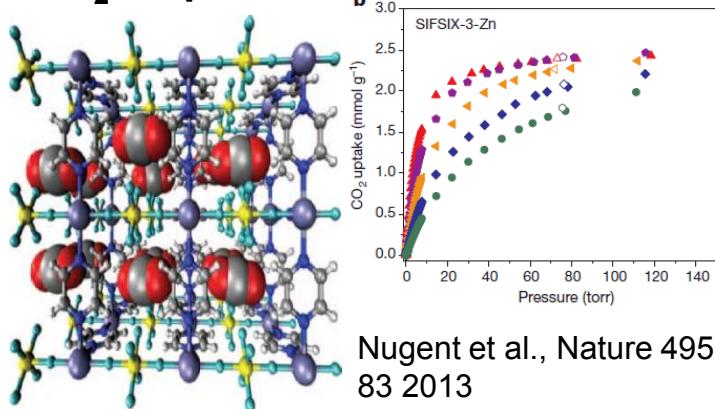


MOFs are a subset of a growing category of self-assembled, nanoporous materials



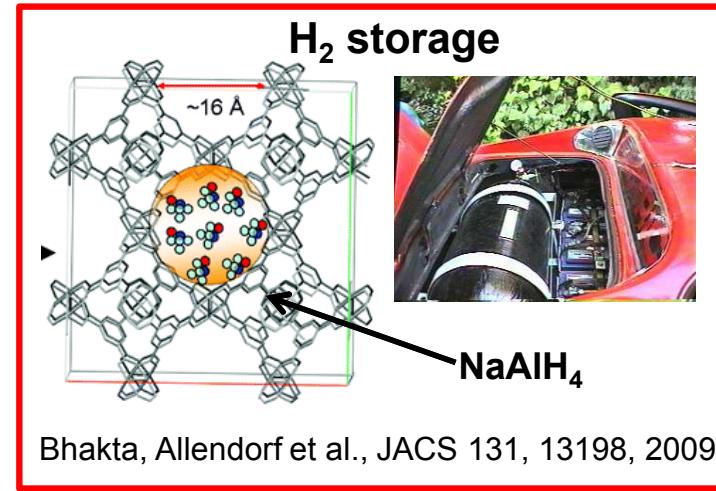
MOFs are attractive for gas storage, catalysis, separations, ionic conductors

CO₂ sequestration



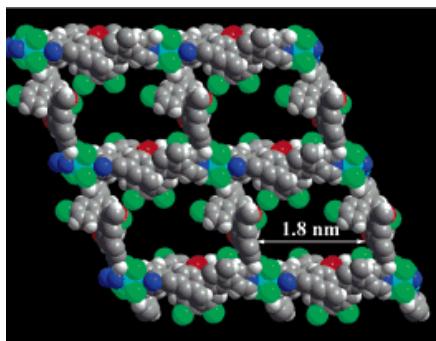
Nugent et al., Nature 495, 83 2013

H₂ storage

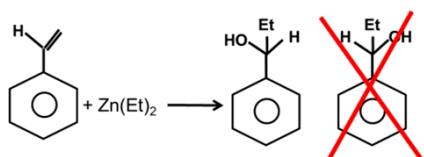


Bhakta, Allendorf et al., JACS 131, 13198, 2009

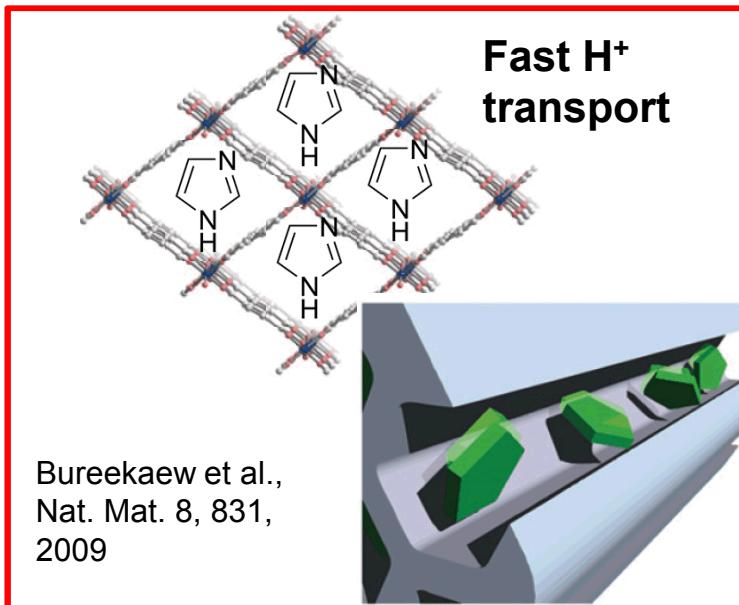
Catalysis



Wu, Hu,
Zhang, Lin
JACS 127,
8940, 2005

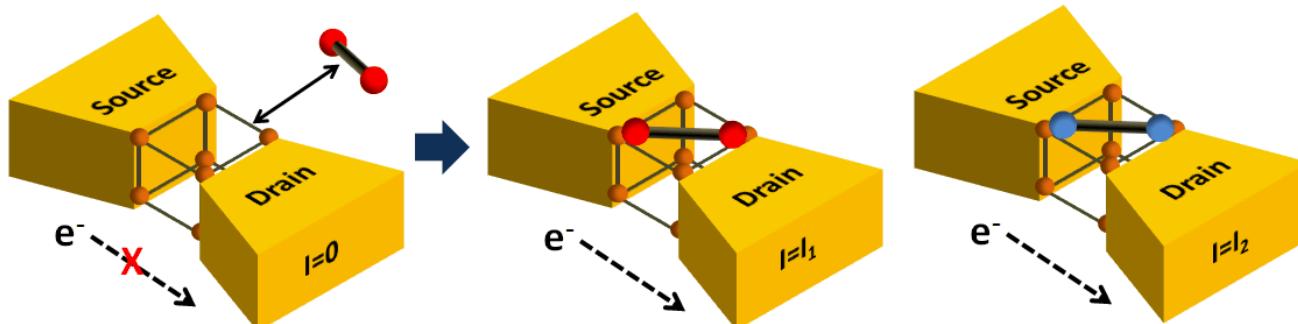
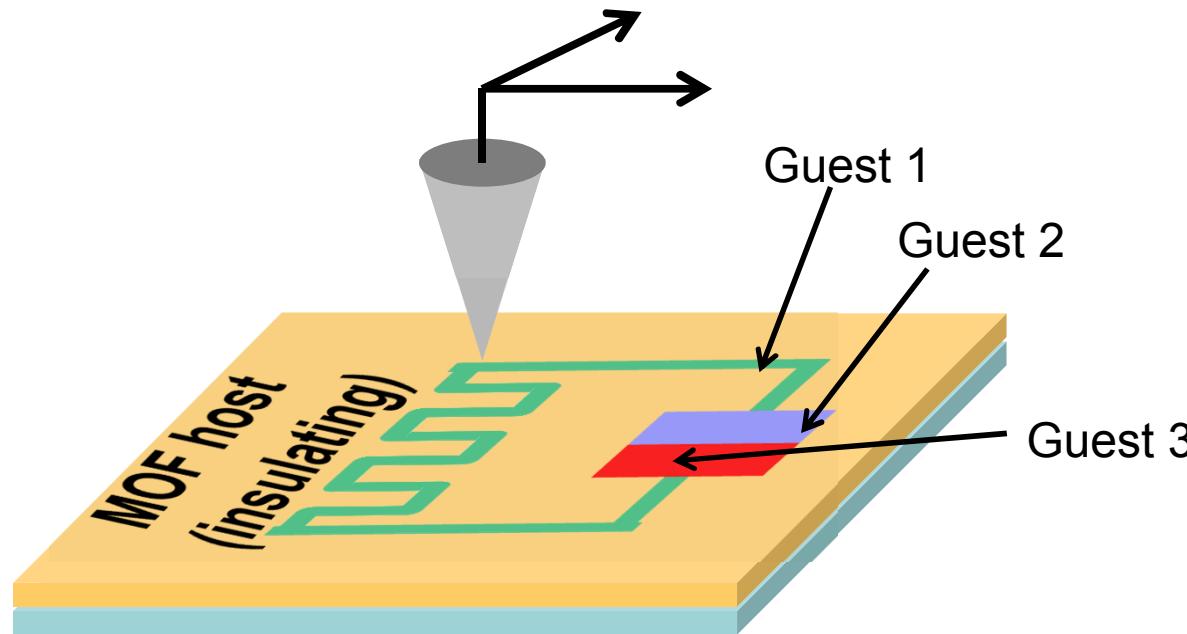


Fast H⁺ transport



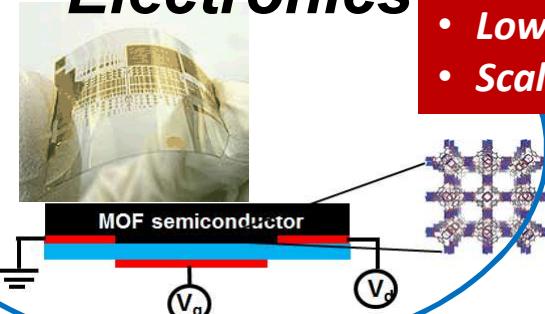
Bureekaew et al.,
Nat. Mat. 8, 831,
2009

Vision for Molecule@MOF ICs, nanodevices

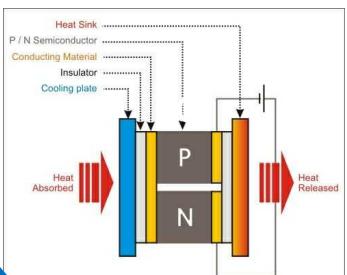


Electronics

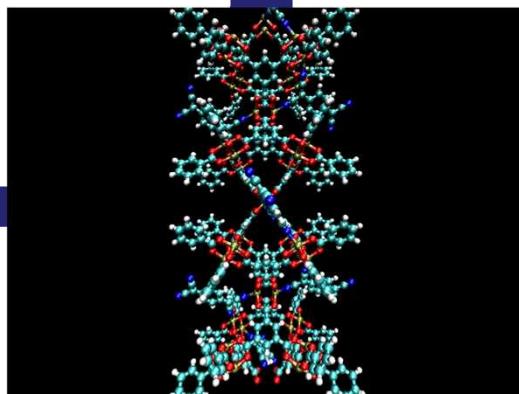
- *Chemically tunable*
- *Low cost, low-T deposition*
- *Scalable down to ~1nm (?)*



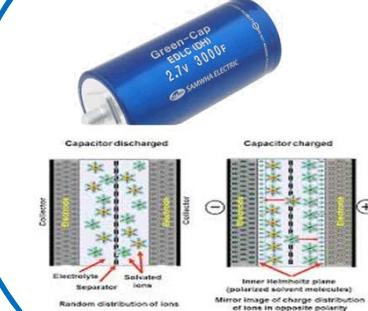
Thermoelectrics



- *Ultrahigh surface area*
- *Redox active centers*

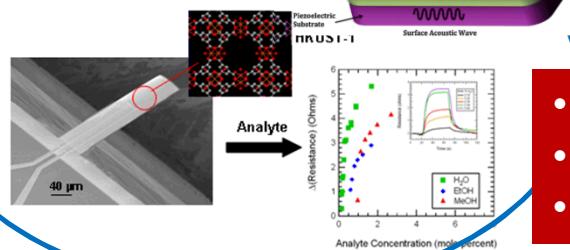


Supercaps



- *Ultrahigh surface area*
- *Redox active centers*

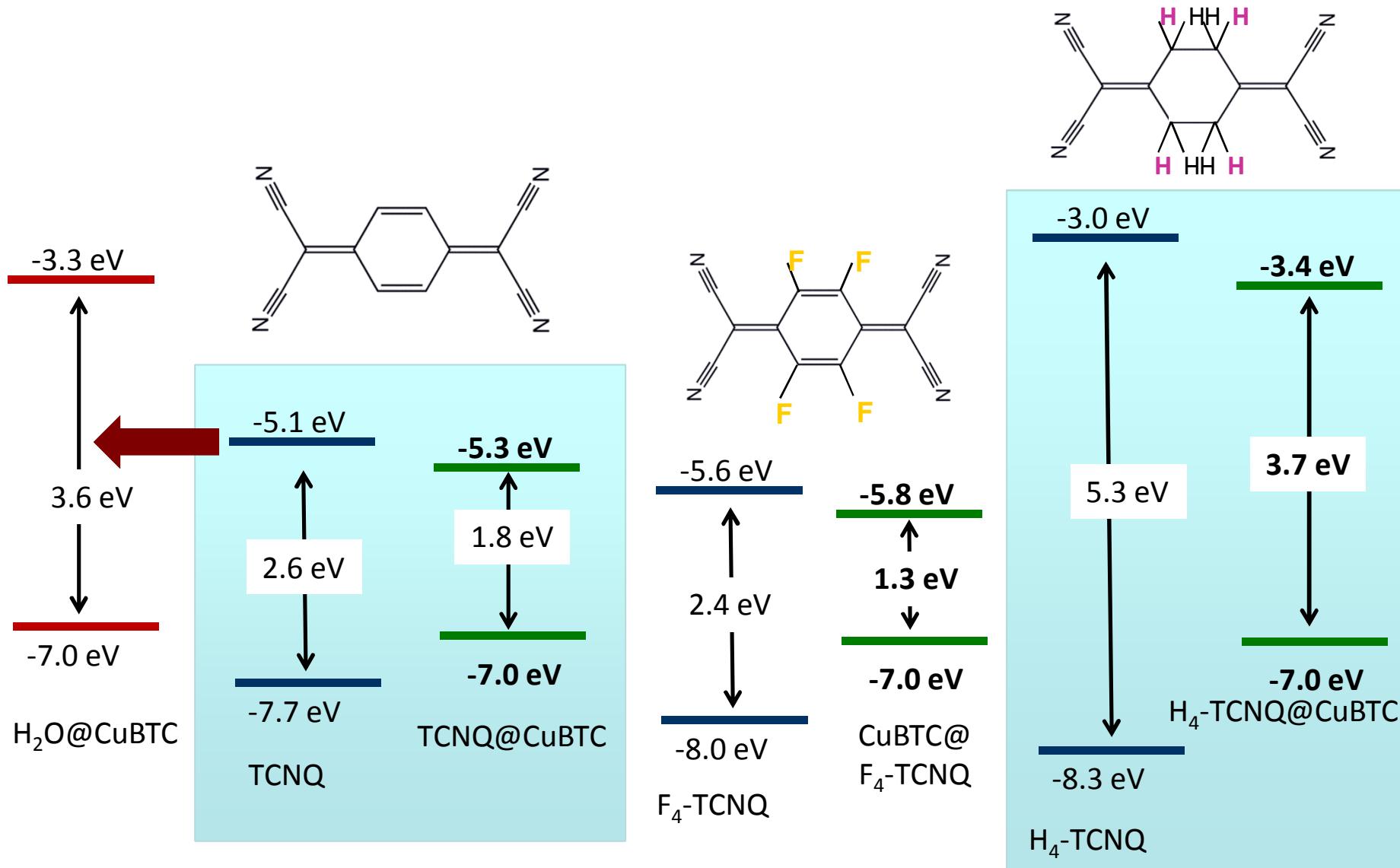
Sensors



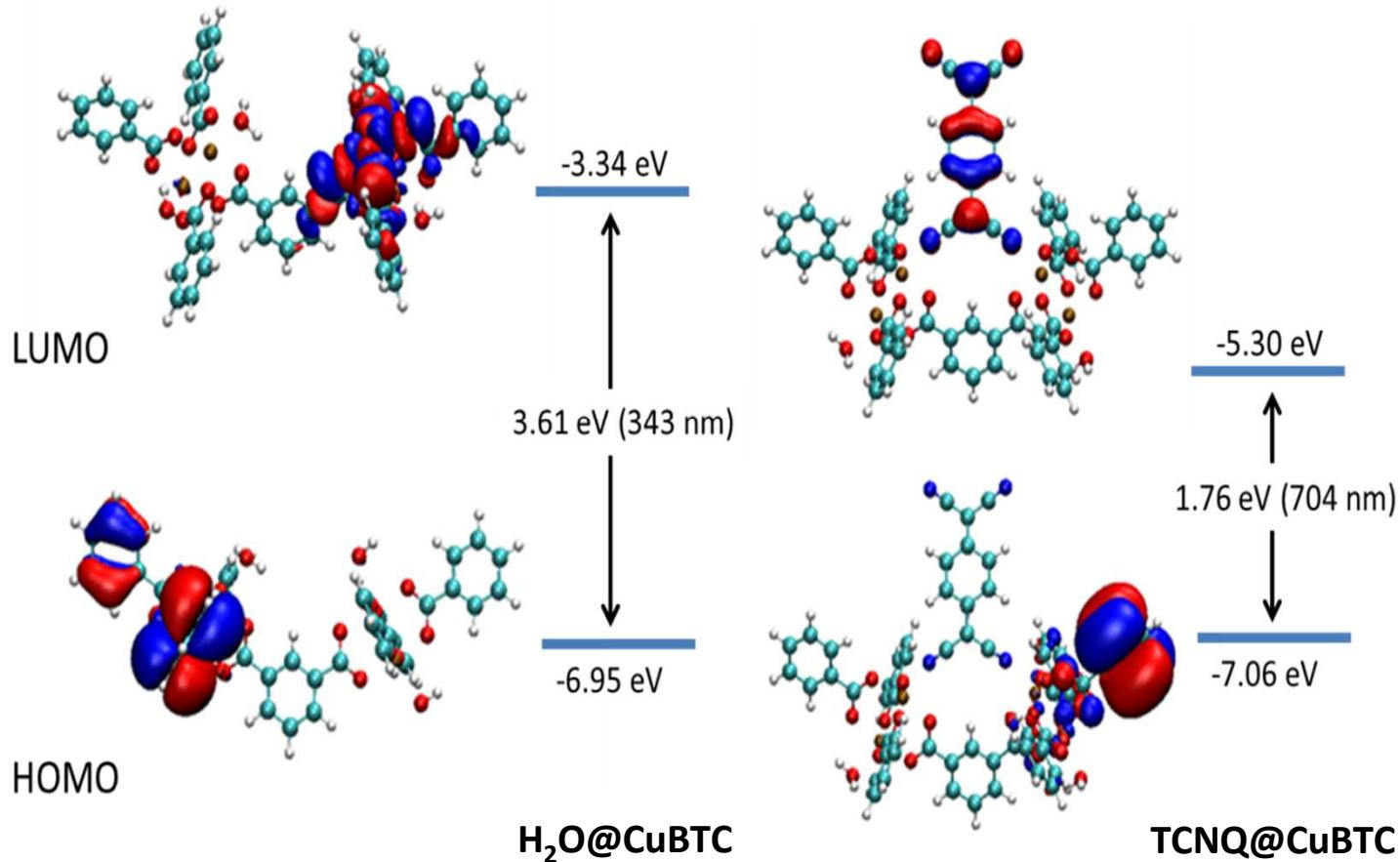
- *Multi-axis response*
- *Chemical specificity*
- *High surface area*

Cu-BTC band alignments: DFT/PBEsol calculations

Effect of fluorination and hydrogenation of TCNQ

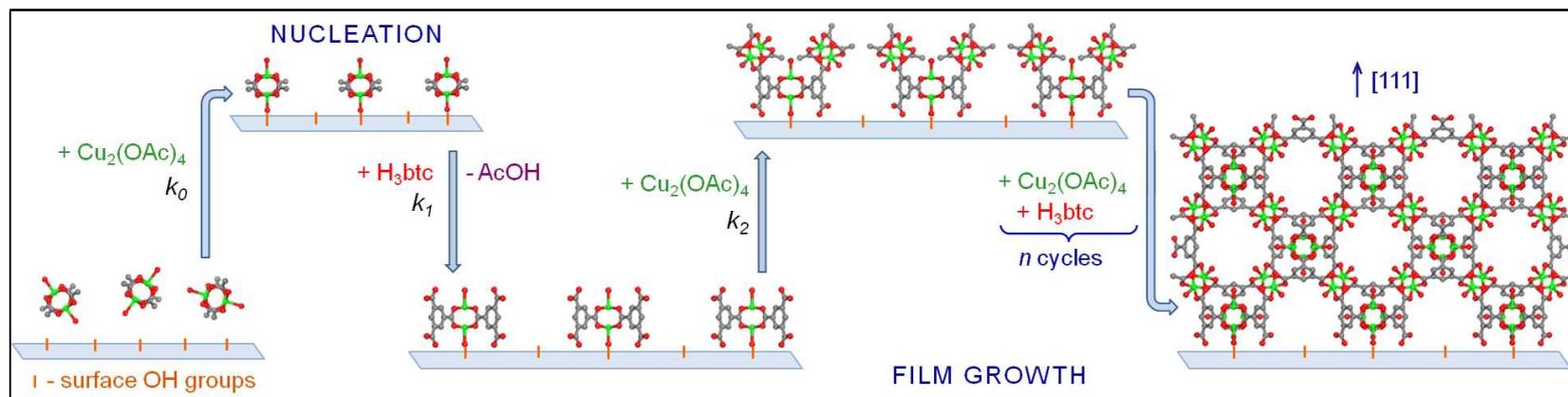
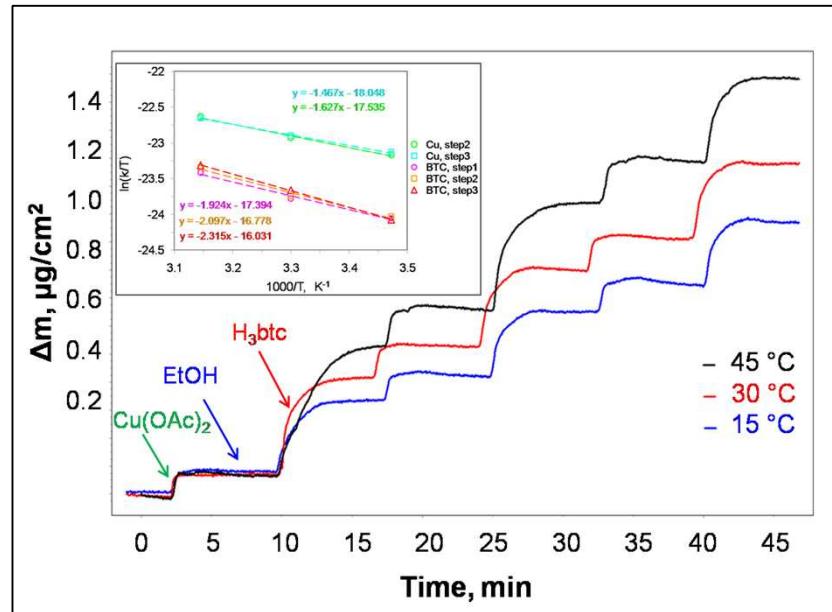


Bridging TCNQ molecules create new charge transfer states

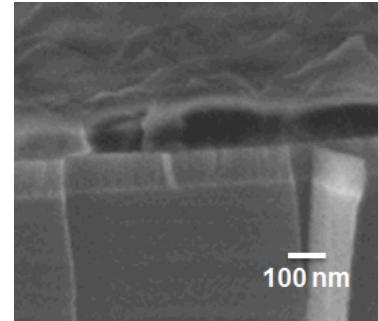
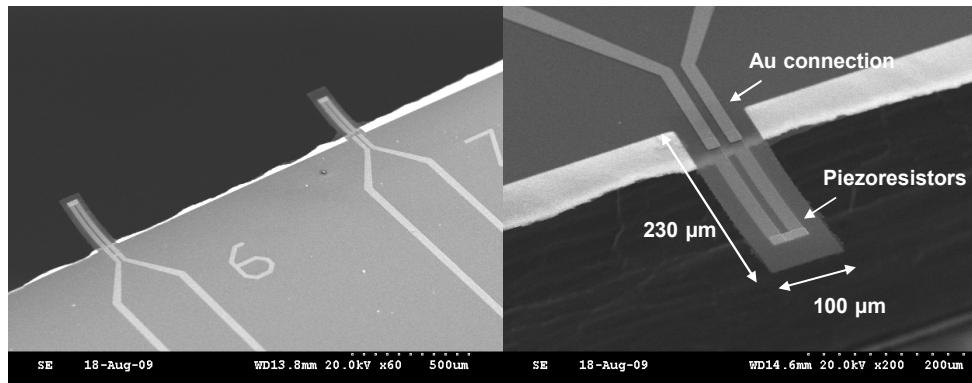


DFT/PBESol calculations

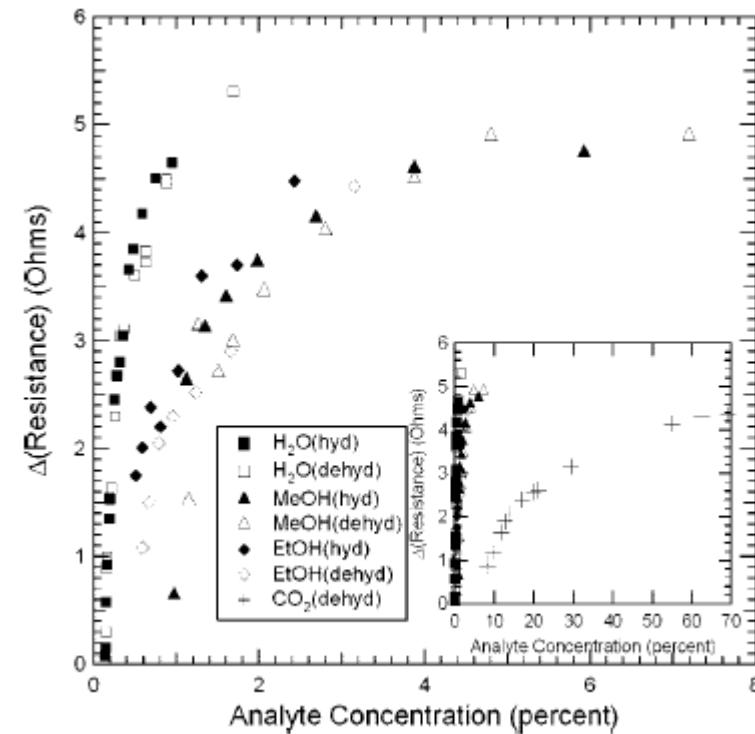
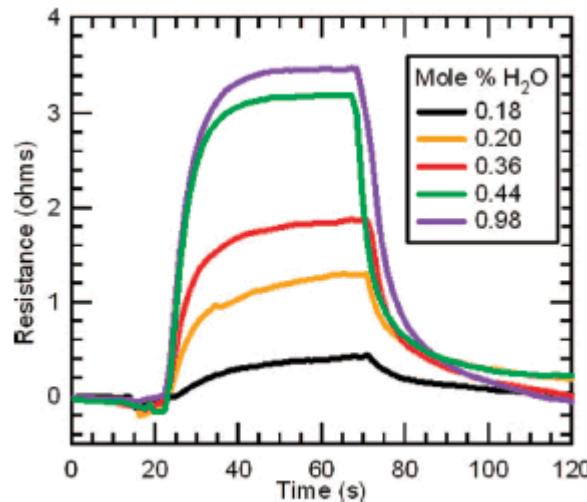
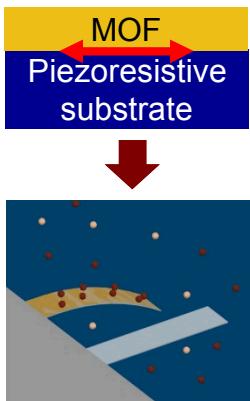
Thin film growth for MOF device applications



MOF films make sensitive, selective gas sensors



Microcantilevers (fg sensitivity)



Allendorf, Talin, Hesketh, et al., *J. Amer. Chem. Soc.* 130, 14404 (2008)